# $X$-ray resonant $m$ agnetic scattering from structurally and m agnetically rough interfaces in m ultilayered system s I. Specular re ectivity 

D.R.Leen D. H askel, Y. Choilin J. C . Lang, S.A. Stepanov, and G . Srajer Advanced P hoton Source, A rgonne N ational Laboratory, A rgonne, Illinois 60439

S. K. Sinha<br>D epartm ent of $P$ hysics, U niversity of C alifomia, San D iego, La Jolla, CA 92093, and Los A lam os N ational Laboratory, Los A lam OS, NM 87545<br>(D ated: M arch 22, 2024)

A bstract
The theoretical form ulation of $x$-ray resonant $m$ agnetic scattering from rough surfaces and interfaces is given for specular re ectivity. A general expression is derived for both structurally and $m$ agnetically rough interfaces in the distorted-wave Bom approxim ation (DW BA) as the fram ework of the theory. For this purpose, we have de ned a \structural" and a \m agnetic" interface to represent the actual interfaces. A generalization of the well-known N evot-C roce form ula for specular re ectivity is obtained for the case of a single rough magnetic interface using the selfconsistent $m$ ethod. Finally, the results are generalized to the case of $m$ ultiple interfaces, as in the case of thin m s or multilayers. Theoretical calculations for each of the cases are illustrated $w$ ith num erical exam ples and com pared w ith experim ental results ofm agnetic re ectivity from a $\mathrm{Gd} / \mathrm{Fe}$ multilayer.

## I. IN TRODUCTION

$X$-ray re ectivity and o specular di use scattering $m$ ethods have been w idely applied over the last decade to characterize the m orphology of rough surfaces and interfaces, particularly w th the availability ofsources ofever-increasing brilliance for x-ray radiation. Sim ilar techniques using neutron beam s have also becom e w idespread, particularly for the study of $m$ agnetic $m$ ultilayers. In the case of $x$-rays, how ever, elem ent-speci cinform ation regarding the $m$ agnetic structure can be readily obtained by tuning the photon energy to that of an L-edge (in the case of transition or rare-earth $m$ etals) ${ }^{n}$ actinides) ${ }^{[14} 1$ gies can result in a large enough signal to be com parable to the dom inant charge scattering.
 inform ation about the $m$ agnetic structure, although the enhancem ent is not as large. Resonant $m$ agnetic scattering corresponds to the real part of the scattering am plitude, while the (absonptive) im aginary part gives rise to x-ray m agnetic circular dichroism (XMCD), which has been used to obtain the values of spin and orbitalm om ents in ferrom agnetic materials. D etailed descriptions of the form alism for the interaction of $x$-rays $w$ th $m$ agnetically polarized atom $s$ have been given in the literature, $m$ agneto-optic phenom ena in the x-ray region can be obtained and applied.

Several resonant $x$-ray specular re ectivity experim ents have been perform ed to obtain the $m$ agnetization $w$ ithin the layens of $m$ agnetic $m$ ultilayers ${ }^{2} 1121012$ results has generally used recursive $m$ atrix techniques developed for $m$ agneto-optics in the case of resonant $x$-ray re ectivity In general, roughness at the interfaces has been ignored or taken into account in an adhoc $m$ anner. In principle, representing roughness in term $s$ of a graded m agnetization at the interface and using slicing $m$ ethods could enable one to calculate the e ect of $m$ agnetic roughness on specular re ectivity at the expense of considerable com putational e ort. R ohlsberger has developed a $m$ atrix form alism (originally developed for nuclear resonant $x$-ray re ectivily) from which specular re ectivity incorporating roughness can be calculated It w it w not considered in his paper, how ever, that the $m$ agnetic interfaces can have di erent roughnesses from the structural (chem ical) ones. In this paper, we de ne separately a stnucturaland a m agnetic interface to represent the actual interfaces and present analytical form ulae taking into account both interface roughnesses,
which provide mudn faster com putationalm ethod than the slicing $m$ ethods and show good agreem ent w ith established form ulae for chem ical interface roughness.

M ethods were developed earlier to calculate analytically the specular com ponent of the charge scattering of $x$-rays by rough surfaces and interfaces using the Bom approxim ation (BA) and the distortedwave Bom approxim ation (DW BA) ? tended to $m$ agnetic interfaces in an earlier publication' ${ }^{1 \text { II }}-1$ and have already been applied to interpreting $x$-ray resonant $m$ agnetic specular re ectivity $m$ easurem ents from $m$ agnetic multilayers 'r.'. H ow ever, the BA or the kinem atical approxim ation breaks down in the vicinity of the criticalangle and below, since it neglects the x-ray refraction. On the other hand, the DW BA takes account ofdynam icale ects, such asmultiple scattering and the x-ray refraction, which becom e signi cant for sm aller angles close to the critical angle and even for greater angles at the resonant energies or w ith soft x-rays. W e present here the generalization of the DW BA to the case of resonant $m$ agnetic $x$-ray re ectivity from rough $m$ agnetic surfaces or interfaces. The principal com plication is, how ever, that we now have to deal w ith a tensor (rather than scalar) scattering length, or equivalently an anisotropic refractive index for $x$-rays ${ }^{11515}$ Th is leads in general to two transm itted and two re ected waves at each interface for arbitrary polarization, which com plicates the DW BA form alism .

The plan of this paper is as follow s. In Sec. II, we discuss a sim ple conceptualm odel for a $m$ agnetic interface and its relationship to the chem ical (i.e., structural) interface and de ne the appropriate $m$ agnetic roughness param eters. In Sec. III, we discuss the (known) scattering am plitudes for resonant x-ray scattering and their relationship to the dielectric susceptibility to be used in the D W BA. In Sec. IV , we present the derivation of the scattering in the DW BA for a single interface $w$ th both structural and $m$ agnetic roughnesses. In Secs. $V$ and $V I$, we derive the form ulae for specular re ectivity from a magnetic interface using the self-consistent method in the fram ew onk of the DW BA and discuss num erical results. F inally, in Secs. V II-IX, we discuss the extension of the form alism to the case of the specular re ectivity from $m$ agnetic $m$ ultilayers and present som e num erical results $w$ ith experim ental data from a Gd/Fe multilayer. In the follow ing paper $r_{-}^{\prime 20} 1$ di use (o -specular) scattering from magnetic interfaces in both the BA and the DW BA.

## II. $\mathrm{M} O \mathrm{DEL} \mathrm{EOR}$ M AGNETIC INTERFACE

Consider an interface betw een a ferrom agnetic medium and a nonm agnetic medium (which could also be free space). D ue to the roughness of this interface, the magnetic m om ents near the interface will nd them selves in anisotropy and exhange elds, which uctuate spatially (see Fig. 1).
$T$ his $w$ ill produce disorder relative to the preferred ferrom agnetic alignm ent w ithin the $m$ agnetic $m$ edium . A sim ilar situation can arise at an interface between a ferrom agnetic $m$ edium ( $F M$ ) and an antiferrom agnetic medium (AFM), where there is a strong antiferro$m$ agnetic coupling betw een spins in the FM and the AFM. R andom steps w ill then produce frustration in the vicinity of the interface, resulting in random disordering of the magnetic $m$ om ents near the interface. C learly in general correlation will exist between the height uctuations of the chem ical interface and the uctuations of the spins, but a quantitative form alism to account for this in detail has not yet been developed. W e $m$ ake here the sim plifying assum ption that the ferrom agnetic $m$ om ents near the interface (or at least their com ponents in the direction of the ferrom agnetic $m$ om ents deep $w$ ithin the FM layer, ie., the direction of average $m$ agnetization $\hat{M}$ ) are cut o at a m athem atical interface, which we call the $m$ agnetic interface and which $m$ ay not coincide $w$ ith the chem ical interface, either in its height uctuations or over its average position, e.g., if a m agnetic \dead layer" exists betw een the two interfaces (see $F i g .1$ ). T he disorder near the interface is thus represented by height uctuations of this $m$ agnetic interface. The basis for this assum ption, whidh is adm iltedly crude, is that the short (i.e., atom ic) length-scale uctuations of the $m$ om ents aw ay from the direction of the average magnetization give rise to di use scattering at fairly large scattering wave vectors, whereas we are dealing here $w$ ith scattering at a sm all wave vector $q$, which represent the relatively slow variations of the average $m$ agnetization density. T he actual interface can be then considered as really com posed of two interfaces, a chem ical interface and a m agnetic interface, each w ith their ow n average height, roughness, and correlation length, and, im portantly, in general possessing correlated height uctuations.
III. RESONANTMAGNETICXRAY SCATTERINGAMPLITUDE

The am plitude for resonant $m$ agnetic scattering of $x$-rays has been derived by $H$ annon et $a l$.' M dM orrow ${ }^{\text {o'q }} \mathrm{T}$ There are two cases of practical im portance, nam ely dipole and quadnupole resonances. W e shall restrict ourselves here to the $m$ ost com $m$ only used dipole resonance, $w h i c h$ is related to the $L$-edges of transition $m$ etals and rare-earth atom $s$. The tensor am plitude for scattering f from a $m$ agnetic atom is given by

$$
\begin{align*}
& \text { X } e_{f} f e_{i}=f_{0}+\frac{3}{8}\left(F_{11}+F_{1}\right)^{\#} e_{f}{ }_{i} e \\
& \frac{3}{8}\left(\begin{array}{lll}
F_{11} & F_{1} & 1
\end{array}\right) e_{f} \quad e_{1} \quad \hat{M} \\
& +\frac{3}{8}\left(2 \mathrm{~F}_{10} \quad \mathrm{~F}_{11} \quad \mathrm{~F}_{1} 10\right) \hat{e}_{f} \hat{M} \quad \hat{e}_{i} \hat{M} \text {; } \tag{3.1}
\end{align*}
$$

$w$ here $e_{i}, \hat{e}_{f}$ are, respectively, the unit photon polarization vectors for the incident and scattered waves, $\hat{M}$ is a unit vector in the direction of the $m$ agnetic $m$ om ent of the atom,
is the x-ray photon wavelength, $f_{0}$ is the usual $T$ hom son (charge) scattering am plitude $\left[f_{0}=\quad f_{0}\left(Z+f^{0} \quad i f^{00}\right)\right]$, where $r_{0}$ is the $T$ hom son scattering length $\left(e^{2}=m C^{2}\right)$, $Z$ is the atom ic num ber, $\mathrm{f}^{0}(<0)$ and $\mathrm{f}^{\infty}(>0)$ are the real and im aginary non-resonant dispersion corrections. $\mathrm{F}_{\mathrm{LM}}$ is the resonant scattering am plitude, as de ned in Ref. ' $\overline{\mathrm{\sigma}}, \mathrm{l}$, and has the resonant denom inator $E_{\text {res }} \quad E \quad i=2$, which provides the resonance $w$ hen the photon energy E is tuned to the resonant energy $\mathrm{E}_{\text {res }}$ close to the absonption edges. T he lifetim e of the resonance is typically $1 \quad 10 \mathrm{eV}$, so that the necessary energy resolution is easily achivable at synchrotron radiation beam lines. (W e assum ed that $q$, the wave-vector transfer, is sm all
 real and im aginary (i.e., absonptive) com ponents. The latter gives rise to the well-known phenom enon of $x$-ray $m$ agnetic circular or linear dichroism, whereas the real part gives rise to the scattering. Equation (

$$
\begin{equation*}
f=A \quad i B^{X} \quad M+C M M ; \tag{32}
\end{equation*}
$$

where

$$
A=f_{0}+\frac{3}{8}\left(F_{11}+F_{1}\right)
$$

$$
\begin{align*}
& B=\frac{3}{8}\left(\begin{array}{lll}
F_{11} & F_{1} & 1
\end{array}\right) ; \\
& C=\frac{3}{8}\left(\begin{array}{lll}
2 F_{10} & F_{11} & F_{11}
\end{array}\right) ; \tag{3.3}
\end{align*}
$$

and , denote C artesian com ponents, and is the antisym $m$ etric Levi-C ivita sym bol
 susceptibility of a resonant $m$ agnetic $m$ edium is given by

$$
\begin{equation*}
\text { resonant }(r)=\frac{4}{\mathrm{k}_{0}^{2}} \mathrm{n}_{\mathrm{m}}(\mathrm{r}) \mathrm{f} \quad(\mathrm{r}) ; \tag{3.4}
\end{equation*}
$$

$w$ here $k_{0}=2=, n_{m}(r)$ is the local num ber density of resonant $m$ agnetic atom $s$, and the variation of $f(r)$ w th $r$ re ects the possible positional dependence of the direction of $m$ agnetization M. T he total dielectric susceptibility is given by

$$
\begin{align*}
& (\mathrm{r})={\frac{4}{\mathrm{k}_{0}^{2}}}^{\mathrm{n}} \quad 0(\mathrm{r}) \mathrm{r}_{0}+A \mathrm{n}_{\mathrm{m}}(\mathrm{r})^{\circ} \tag{3.5}
\end{align*}
$$

where $o(r)$ represents the electron num ber density arising from all the other nonresonant atom $s$ in the $m$ edium $m$ odi ed by their anom alous dispersion corrections when necessary. U sing the constitutive relationship between the local dielectric constant tensor (r) and (r),

$$
\begin{equation*}
(r)=\quad+\quad(r): \tag{3.6}
\end{equation*}
$$

W e note that the m agnetization gives the dielectric tensor the sam e sym m etry as in conventionalm agneto-optic theory, nam ely an antisym $m$ etric com ponent linear in the $m$ agnetization.
IV. THE D ISTORTED-W AVE BORN APPROXIM ATION FOR A SINGLEMAGNETIC INTERFACE

The results for specular re ectivity in the Bom approxim ation (BA) have been derived in Ref. 'ī19, and will be also sum marized brie $y$ in connection $w$ ith the cross section in the follow ing paper'ia!' H ere we discuss the scattering in term $s$ of the distorted-w ave Bom approxim ation (D W BA ). W hile this is m ore com plicated algebraically, it provides a better
description than the sim ple kinem aticalapproxim ation or BA in the vicinity of regionswhere total re ection or B ragg scattering occurs．This treatm ent is a generalization of that used in $R$ ef． $1 i \bar{i} \overline{-1}$, for charge scattering．The wave equation for electrom agnetic waves propagating in an anisotropic $m$ edium w ith a dielectric susceptibility tensor given by Eq．（3̄） w ritten as

$$
\begin{equation*}
x \quad r\left(r^{2}+k_{0}^{2}\right) \quad r r+k_{0}^{2} \quad{ }^{i} E(r)=0 ; \quad(;=x ; y ; z) ; \tag{4.1}
\end{equation*}
$$

where $E(r)$ is the electric eld vector．
C onsider a wave incident，as in $F$ ig．II＿1 w ith wave vector $k_{i}$ in the $(x ; z)$ plane $\left(k_{i, y}=0\right)$ and polarization（＝or ），from a nonm agnetic（isotropic）medium forwhich $=0$ onto a sm ooth interface at $z=0 \mathrm{w}$ th a m agnetic m edium，for $w$ hich is constant for $z<0$ ．

Let usw rite for $z<0$

$$
\begin{equation*}
=1+(2) ; \tag{42}
\end{equation*}
$$

where the term ${ }^{(2)}$ is the part that speci cally depends on them agnetization $M$ ，as de ned in Eq．（ $\overline{3}$ ．⿹弓冫）$)$ ．The incident wave（chosen for convenience $w$ th unit am plitude）$m$ ay be written as

$$
\begin{equation*}
E^{i}(r)=e e^{i k_{i}} \check{r} \tag{4.3}
\end{equation*}
$$

This incident wave will in general give rise to two specularly re ected waves（where the index refers to or polarization）and two transm itted（refracted）waves in the $m$ agnetic $m$ edium．The com plete solution for the electric eld in the case of the $s m$ ooth $m$ agnetic interface is then given by

$$
\begin{align*}
\left.E_{\left(k_{i} ;\right.}\right)(r) & =\hat{e} e^{i k_{i} r_{+}} \quad x \quad R^{(0)}\left(k_{i}\right) e e^{i k_{i}^{r}} ; z>0 ; \\
& =x{ }_{j=1 ; 2}^{T_{j}^{(0)}\left(k_{i}\right) e_{j} e^{i k_{i}^{t}(j)} ; z<0 ;} \tag{4.4}
\end{align*}
$$

$w$ here $k_{i}^{r}$ is the specularly re ected wave vector in the nonm agnetic $m$ edium，denotes the polarization of the appropriate re ected component，the index $j(=1 ; 2)$ de nes the com ponent of the transm itted wave in the $m$ agnetic resonant medium with polarization $\hat{e}_{j}$ $\left(e_{j=1 ; 2}=e^{(1)}\right.$ and $e^{(2)}$ ，respectively，as de ned in A ppendix A），and $k_{i}^{t}(j)$ the appropriate
w ave vector for that transm itted wave. The polarization vectors e may be real or com plex allow ing for linear or elliptically polarized waves. We denote such states in Eq. ( $\bar{A}-\overline{4}$ ) quantum -m echanically by $\mathrm{k}_{\mathrm{i}}$; >.
$\mathrm{R}^{(0)}$ and $\mathrm{T}_{j}{ }^{(0)}$ denote the appropriate re ection and transm ission coe cients for the sm ooth surface and are expressed in term sof 22 m atrices using the polarization bases for the incident and re ected (or transm itted) waves. The polarization basis is given by (e , e ), as show $n$ in $F$ ig. 1, for the waves in the nonm agnetic $m$ edium and $\left(e^{(1)}, e^{(2)}\right)$, as de ned in A ppendix $A$, for those in the $m$ agnetic resonant $m$ edium, respectively. The convention in which the polarization state of the re ected (or transm itted) wave precedes that of the incident wave is used for the subscripts in $R^{(0)}$ and $T_{j}{ }^{(0)}$, and the $G$ reek and $R$ om an letters are used for the polarization states in the nonm agnetic and $m$ agnetic $m$ edium, respectively. $T$ he explicit expressions ofR ${ }^{(0)}$ and $T_{j}^{(0)}$ for sm allangles of incidence and sm allam plitudes of the dielectric susceptibility and for specialdirections of the polarization and m agnetization (ie., $\mathrm{M} \mathrm{k} \hat{\mathrm{x}}$ as shown in F ig. 1) are given in Appendix A.

W e should $m$ ention, how ever, that these speci c conditions considered in A ppendix A (and also in all other appendices) are reasonably satis ed for hard-and medium -energy $x$ rays and also for soft x-rays around transition-m etal L-edges $w$ th sm all angles (i.e., when ${ }_{i} \quad 1$ for the incidence angle ${ }_{i}$ ). We should also mention that, even when $M$ is not parallel to the $\hat{x}$-axis in $F$ ig. 1, the expressions derived in the appendioes can be still applied by considering only the $x$-com ponent of them agnetization vector $M . T$ his is because the y - and z -com ponents of M contribute negligibly to the scattering in com parison w th
 $F_{11} \quad F_{1} 1_{j} \quad \dot{2} F_{10} \quad F_{11} \quad F_{11} j$ which is generally satis ed for transition-m etal and rare-earth L-edges.i.'

W e note that the continuity of the elds parallel to the interface requires that

$$
\begin{equation*}
\left(\mathrm{k}_{\mathrm{i}}\right)_{\mathrm{k}}=\left(\mathrm{k}_{\mathrm{i}}^{\mathrm{r}}\right)_{\mathrm{k}}=\mathrm{k}_{\mathrm{i}}^{\mathrm{t}}(\mathrm{j})_{\mathrm{k}} ; \tag{4.5}
\end{equation*}
$$

where ()$_{k}$ denotes the vector com ponent parallel to the interface.
W e now discuss the structurally and magnetically rough interface. For this purpose we shall assum e that the average height (along $z$ ) of the structural and $m$ agnetic interfaces is the sam e, i.e., we ignore the presence of a $m$ agnetic dead layer. This $m$ ay be treated w ithin the DW BA as simply another nonm agnetic layer and thus discussed within the form alism
for treating $m$ ultilayers as discussed in Section VII. W e can write

$$
\begin{equation*}
(r)={ }^{(0)}(r)+c^{c}(r)+{ }^{m}(r) ; \tag{4.6}
\end{equation*}
$$

where

$$
\begin{align*}
& { }^{(0)}(\mathrm{r})=0 \quad ; \quad \mathrm{z}>0 \\
& =1+{ }^{(2)} ; \mathrm{z}<0 \text {; }  \tag{4.7}\\
& { }^{c}(r)=\left(\begin{array}{ll}
1 & 0
\end{array}\right) \quad ; \text { for } 0<z<z_{e}(x ; y) \text { if } z(x ; y)>0 \\
& =\left(\begin{array}{ll}
1 & 0
\end{array}\right) \quad \text {; for } z_{e}(x ; y)<z<0 \text { if } z(x ; y)<0 \\
& =0 \text { elsew here; } \tag{4.8}
\end{align*}
$$

and

$$
\begin{align*}
\mathrm{m}(r) & ={ }^{(2)} ; \text { for } 0<z<\quad z_{n}(x ; y) \text { if } \quad z_{n}(x ; y)>0 \\
& =\quad{ }^{(2)} ; \text { for } \quad \mathrm{m}_{n}(x ; y)<z<0 \text { if } \quad z_{n}(x ; y)<0 \\
& =0 \quad \text { elsew here; } \tag{4.9}
\end{align*}
$$

$z_{e}(x ; y)$ and $\quad z_{n}(x ; y)$ de ne the structural (chem ical) and $m$ agnetic interfaces, respectively. W em ay also de ne the tim e-reversed fiunction corresponding to a wave incident on the interface w ith vector ( $k_{f}$ ) and polarization as

$$
\begin{align*}
& E_{\left(k_{f} ;\right)}^{T}(r)=e e^{i k_{f} r_{+}} \quad X^{X} R^{(0)}\left(k_{f}\right) e e^{i k_{f}^{r}} r_{j}^{r} z>0 \\
& ={\underset{j=1 ; 2}{X} T_{j}^{(0)}\left(k_{f}\right) e_{j} e^{i k_{f}^{t}}(j) \underset{i}{r} z<0 ; ~}_{z} \tag{4.10}
\end{align*}
$$

where ( $k_{f}^{r}$ ) is the wave vector of the wave specularly re ected from ( $k_{f}$ ), and $k_{f}^{t}(j)$ is the wave vector of one of the two transm itted waves in the $m$ edium em anating from ( $\mathrm{k}_{\mathrm{f}}$ ) incident on the surface, as shown in Fig. in. N ote that, for consistency w th the
 ordinary coordinate system where their phases are considered along the left-to-right direction in $F$ ig. 1. O therw ise, the polarization vectors in Eq. (4̄) (1]) should be replaced by their com plex con jugates.

W e have also the conditions

$$
\begin{equation*}
\left(k_{f}\right)_{k}=\left(k_{f}^{r}\right)_{k}=k_{f}^{t}(j)_{k}: \tag{4.11}
\end{equation*}
$$

The DW BA then yields the di erential cross section for scattering by the rough interface from ( $\mathrm{k}_{\mathrm{i}}$; ) to ( $\mathrm{k}_{\mathrm{f}}$; ) as

$$
\begin{equation*}
\frac{\mathrm{d}}{\mathrm{~d}}={\frac{1}{16^{2}}}^{\mathrm{D}} \mathbb{T}^{\mathrm{fi}} \mathrm{~J}^{\mathrm{E}} ; \tag{4.12}
\end{equation*}
$$

 denotes a statistical averaging over random uctuations at the interface. Follow ing R ef. 'ī̄], we split the cross section into tw o parts:

$$
\begin{equation*}
\frac{d}{d}=\frac{1}{16^{2}} \mathrm{~T}^{\mathrm{fi}} \mathrm{E}_{2}+\frac{1}{16^{2}}{ }^{\mathrm{D}} \mathrm{~T}^{f i} \stackrel{J}{\mathrm{~J}}^{\mathrm{E}} \mathrm{D}_{\mathrm{fi}}^{\mathrm{E}_{2}}: \tag{4.13}
\end{equation*}
$$

The rst term in Eq. (A. corresponds to a statistical averaging of the scattering am plitude, and the second term corresponds to the incoherent (di use) scattering. In this paper, we shall dealw ith the rst term only, while the di use scattering w ill be addressed in the follow ing paper'ㄴㅇ́:

The DW BA consists of approxim ating the scattering $m$ atrix elem ent by the expression

$$
\begin{align*}
<\mathrm{k}_{\mathrm{f}} ; ~ \mathfrak{~ J ~} \mathrm{k}_{\mathrm{i}} ;> & =\mathrm{k}_{0}^{2}<\mathrm{k}_{\mathrm{f}}^{\mathrm{T}} ; \mathrm{j}^{(0)} \mathrm{F}^{\mathrm{i}}(\mathrm{r})> \\
& +\mathrm{k}_{0}^{2}<\mathrm{k}_{\mathrm{f}}^{\mathrm{T}} ; \mathrm{j}^{\mathrm{c}} \mathrm{k}_{\mathrm{i}} ;>+\mathrm{k}_{0}^{2}<\mathrm{k}_{\mathrm{f}}^{\mathrm{T}} ; j^{\mathrm{m}} \mathrm{k}_{\mathrm{i}} ;>: \tag{4.14}
\end{align*}
$$


 and ${ }^{m}$ with the vector elds $<k_{f}^{T}$; jand $<k_{i}$; j.W hile ${ }^{(0)}$ represents an idealsystem $w$ ith a sm ooth interface, ${ }^{c}$ and ${ }^{m}$ are perturbations on ${ }^{(0)}$ due to interface roughnesses.

For the sm ooth surface, only the rst tensor is nonvanishing, and, follow ing Ref. can show from Eqs. (

$$
\begin{align*}
& k_{0}^{2}<k_{f}^{T} ; j^{(0)} E^{i}(r)>=i A k_{0}^{2} k_{k_{i x} k_{f x}} \mathrm{k}_{\mathrm{iy}} \mathrm{k}_{\mathrm{fy}} \\
& { }^{X} T_{j}^{(0)}\left(k_{f}\right)^{X} e_{j}\left(1+{ }^{(2)}\right) e \\
& Z_{0}^{j} \\
& d z e^{i\left(k_{\mathrm{fz}}^{\mathrm{t}}(j) \mathrm{k}_{\mathrm{iz}}\right) z} ; \\
& =2 i A k_{i z} R^{(0)}\left(k_{i}\right) k_{\text {ix }} k_{f x} k_{\text {iy }} k_{f y} \text {; } \tag{4.15}
\end{align*}
$$

where $A$ is the illum inated surface area, and $R{ }^{(0)}\left(k_{i}\right)$ is the re ection coe cient for the

 the rough surface in Eq. (4) 14

$$
\begin{equation*}
\left\langle\mathrm{k}_{\mathrm{f}} ; \text { 打 } \mathrm{k}_{\mathrm{i}} ; \quad>=2 i A \mathrm{k}_{\mathrm{iz}} \mathrm{R} \quad\left(\mathrm{k}_{\mathrm{i}}\right)_{\mathrm{k}_{\mathrm{i} x} \mathrm{k}_{\mathrm{fx}}} \mathrm{k}_{\mathrm{iy}} \mathrm{k}_{\mathrm{fy}} ;\right. \tag{4.16}
\end{equation*}
$$

where $R \quad\left(k_{i}\right)$ denotes the re ection coe cient for the rough surface.
O $n$ the other hand, for the reverse case where $a$ w ave is incident from a resonant $m$ agnetic $m$ edium to a nonm agnetic (isotropic) $m$ edium , smilarly to Eq. ( 4 in 1 ), the scattering $m$ atrix elem ent for the $s m$ ooth surface can be shown to be

$$
\begin{equation*}
k_{0}^{2}<\quad k_{f}^{T} ; j^{0} j^{(0)} k_{i} ; j>=4 i A k_{i z}(j) R_{j^{0} j}^{(0)}\left(k_{i}\right) k_{i x} k_{f x} k_{i y} k_{f y} ; \tag{4.17}
\end{equation*}
$$

where the incom ing wave from the resonant $m$ agnetic $m$ edium $\mathrm{k}_{\mathrm{i}} ; j>$ is used instead of
 and ( $\overline{4} \cdot \overline{1} \overline{1} \overline{1})$ in Eqs. ( $\overline{4} \cdot \overline{1} \overline{1} \overline{1})$ and ( $\overline{1} \cdot \overline{1} \overline{1} \overline{2})$ in the case of the sm ooth surface and the derivation of the corresponding re ectivity in the usualm anner, as discussed in Ref. Eqs. ( $\overline{4} .1$ scattering $m$ atrix elem ent for the rough surface betw een reversed layers can be also de ned by analogy from Eq. ( $\overline{4} \overline{1} \overline{-1}-1)$ as

$$
\begin{equation*}
\left\langle\mathrm{k}_{\mathrm{f}} ; j^{0} \mathrm{j} \mathrm{j} \mathrm{k}_{\mathrm{i}} ; j\right\rangle=4 \mathrm{iA} \mathrm{k}_{\mathrm{iz}}(\mathrm{j}) \mathrm{R}_{\mathrm{j}^{0} j}\left(\mathrm{k}_{\mathrm{i}}\right)_{\mathrm{k}_{\mathrm{ixx}} k_{\mathrm{fx}}} \mathrm{k}_{\mathrm{iy}} \mathrm{k}_{\mathrm{fy}} ; \tag{4.18}
\end{equation*}
$$

$w h e r e R_{j 0}{ }_{j}\left(k_{i}\right)$ denotes the re ection coe cient for the rough surface betw een reversed layers.
V. REFLECTION AND TRANSM ISSION COEFFICIENTSUSING THE SELFCONSISTENTMETHOD

To calculate specular re ectivity, we $m$ ake an approxim ation in the spirit of $N$ evot and
 for $\mathrm{E}\left(\mathrm{k}_{\mathrm{i}} ;\right.$ ) in Eq. (4) 4 . 4 ) the functional form for $\mathrm{z}>0$ analytically continued for $\mathrm{z}<0$, while for the tim e-reversed state $\mathrm{E}^{\mathrm{T}}\left(\mathrm{k}_{\mathrm{f}} ;\right.$ ) in Eq. ( $(\overline{4}-1 \mathbf{0})$ the functional form for $\mathrm{z}<0$ analytically continued to $z>0$. Then, bearing in $m$ ind that for specular re ectivity $k_{f}=k_{i}^{r}$ and using Eq. ( $\overline{4} \cdot \mathbf{-} \mathbf{N}_{1}$ ), we obtain for the statistically averaged am plitude $\mathrm{T}^{\mathrm{D}}{ }^{\mathrm{E}}$ :

$$
\mathrm{k}_{0}^{2}<\mathrm{k}_{\mathrm{f}}^{\mathrm{T}} ; j^{\mathrm{c} ; \mathrm{m}} \mathrm{k}_{\mathrm{i}} ; \gg^{\mathrm{E}}=\mathrm{iA} \mathrm{k}_{0}^{2}{ }_{j=1 ; 2}^{\mathrm{X}} \mathrm{~T}_{j}^{(0)}\left(\mathrm{k}_{\mathrm{f}}\right)
$$

$$
\begin{aligned}
& \text { "X } \frac{e_{j}^{c ; m} e}{q_{1 z}(j)} e^{D q_{1 z}(j) z_{c ; m}(x ; y)}{ }^{E} \quad 1
\end{aligned}
$$

where

$$
\begin{equation*}
g_{I z}(j)=k_{f z}^{t}(j) \quad k_{f_{z}} ; \quad g_{z z}(j)=k_{f z}^{t}(j) \quad k_{f_{z}}^{f} ; \tag{52}
\end{equation*}
$$

 (4)-1

$$
\begin{equation*}
\mathrm{R}=\mathrm{R}^{(0)}+\mathrm{U}+{ }^{\mathrm{X}} \mathrm{~V} \mathrm{R}^{(0)} \text {; } \tag{5.3}
\end{equation*}
$$

where
and replacing $q_{z z}$, $e$ in $U$ by $q_{z}$, e produces $V$. Here we $m$ ade the custom ary $G$ aussian approxim ation for the height uctuations $z_{c ; n}(x ; y)$, and $c, m$ are the root-m ean-squared structural and $m$ agnetic roughnesses, respectively. $N$ ote that the correlation term $U$ due to the roughness in the re ection coe cient contains only independent contributions of chem ical and $m$ agnetic roughnesses expressed via $c$ and $m$, respectively. A coording to Eq. (44.13), the di use scattering $m$ ust contain the cross-correlation com ponent due to the term


A better approxim ation than Eq. (5.-ָ.j) m ay be obtained by using the rough-interface re ection coe cient $R$ instead of the $s m$ ooth-interface $R{ }^{(0)}$ in the wave functions of Eqs.
 $\mathrm{R}, \mathrm{U}, \mathrm{V} . \mathrm{Th}$ is leads to

$$
\begin{equation*}
R=R^{(0)}+U+V R ; \tag{5.5}
\end{equation*}
$$

whose solution is

$$
R=\left(\begin{array}{ll}
1 & V \tag{5.6}
\end{array}\right)^{1}\left(\mathbb{R}^{(0)}+U\right):
$$

Sim ilarly, for the reverse interface betw een upper resonant $m$ agnetic and low er nonm agnetic layers, we can have the sam e solution as Eq. (5. expressions of $U, V, R{ }^{(0)} \mathrm{m}$ atrioes in Eq. (5). (G) for both cases are given in A ppendix C .

For nonm agnetic interfaces, the $m$ atrioes are all diagonal( and polarizations are decoupled), and it has been show n that Eq. (5.") leads to the fam iliar $N$ evot-C roce form for the re ection coe cient, i.e.,

$$
\begin{equation*}
R=R^{(0)} e^{2 \mathrm{k}_{z} \mathrm{jk}_{\mathrm{t}}^{\mathrm{t}} \mathrm{j}_{\mathrm{c}}^{2}}: \tag{5.7}
\end{equation*}
$$

The derivation of this is shown in A ppendix D. For the m agnetic interfaœe, this sim pli ed form for the re ection coe cient does not have any analogue. Nevertheless, at su ciently large values of $q_{2}$, the re ectivity takes the fam iliar $G$ aussian form $R^{(0)} e^{q_{2}^{2}} e_{e}^{2}$. H ow ever, ${ }_{e}^{2}$ does not alw ays take the form predicted by the sim ple kinem atical theory [i.e., ${ }_{c}^{2}$ for ! re ectivity, ${\underset{m}{2}}_{2}$ for ! re ectivity, and $\frac{1}{2}(\underset{c}{2}+\underset{m}{2})$ for ( $\left.I_{+} \quad I\right)$ in the case of circularly polarized $x$-rays] as we shall in the num erical exam ple shown below, which provides a counter-illustration of the rule that, at large $q_{2}$, the DW BA becom es identical to the Bom approxim ation or kinem atical lim it.

For circularly polarized incident x-rays with e $\left(\widetilde{K}_{i}\right)=$ e $\left({\widetilde{K_{i}}}_{i}\right) \quad$ ie $\left(\widetilde{K}_{i}\right)=\stackrel{p}{=} \overline{2}$, the re ection am plitudes for -and -polarization are given by
whereR is the 2 m atrix re ection coe cient in Eq. ( $5 . \overline{6} . \overline{2}$. The re ected intensities w ithout polarization analysis for the outgoing beam, $I=\frac{q}{R-j+R} f$, can be then evaluated for the opposite helicities of incident beam s as

$$
\begin{equation*}
\left.I_{+} \quad I=2 \operatorname{Im} \mathbb{R}_{11} R_{12}+R_{21} R_{22}\right] ; \tag{5.9}
\end{equation*}
$$

$w$ here $R_{i j}$ is the $i j$-elem ent of the $2 \quad 2 \mathrm{~m}$ atrix R .
Since Parratt's recursive form ula for multiple interfaces includes only re ection coe cients, its extension to the rough interface case does not need the transm ission coe cient to account for interface roughness. On the other hand, in our case where the elds are not scalars, the transm ission coe cients are requisite to calculate recursive 22 m atrix form ulae for m ultiple m agnetic interfaces, which will be discussed in Sec. V II. For com pleteness,
therefore, let us now calculate the transm ission coe cient $T_{j}$ from a rough interface. In the spirit of Ref. ${ }^{1} \underline{-1} \overline{-1}$, we assum $e$ for $E\left(k_{i} ;\right)$ and $E^{T}\left(k_{f} ; j\right)$ the functional form $s$ analytically continued both for $z>0$ and for $z<0$ as follow $s$ :
where $T_{j}^{(0)}\left(k_{f}\right)$ in Eq. (5. $\left.\overline{1} \overline{1} \overline{1}^{\prime}\right)$ denotes the transm ission coe cient \from " a magnetic (anisotropic) m edium \to" a nonm agnetic (isotropic) one, whose explicit form is given in A ppendix A. For the sm ooth surface, the scattering $m$ atrix elem ent betw een the eigenstates $j \quad k_{f}^{T} ; j>$ and $k_{i} ;>$ can be then written as

$$
\begin{align*}
& \mathrm{k}_{0}^{2}<\mathrm{k}_{\mathrm{f}}^{\mathrm{T}} ; \mathrm{j}^{(0)} \mathrm{k}_{\mathrm{i}} ;>=\mathrm{iA} \mathrm{k}_{0}^{2} \mathrm{k}_{\mathrm{ixx}} \mathrm{k}_{\mathrm{fx}} \mathrm{k}_{\mathrm{iyy}} \mathrm{k}_{\mathrm{fy}} \\
& { }^{X} T_{j}^{(0)}\left(k_{f}\right)^{X}{ }_{j^{0}} T_{j^{0}}^{(0)}\left(k_{i}\right)^{X} \text { e }\left(1 \quad+{ }^{(2)}\right) e_{j 0} \\
& \text { Z } 0 \\
& \text { dze }{ }^{i\left(k_{f z} k_{\text {iz }}^{\mathrm{t}}\left(j^{0}\right)\right)} \text {; } \\
& 1 \\
& =4 i A k_{i z}^{t}(j) T_{j}^{(0)}\left(k_{i}\right) k_{i x} k_{f x} k_{i y} k_{f y} ; \tag{5.12}
\end{align*}
$$

where $T_{j}^{(0)}\left(k_{i}\right)$ is the transm ission coe cient for the sm ooth surface, as de ned in Eq. (4.4) $)^{\prime}$. The details of Eqs. (5, 5

In com parison w ith Eq. ( 5 the rough surface, as show in Eq. ( $\overline{4} \bar{H}_{1} \overline{1}_{1}^{\prime}$ ), can be analogously de ned by

$$
\begin{equation*}
\left\langle\mathrm{k}_{\mathrm{f}} ; j \mathrm{j} \Gamma \mathrm{k}_{\mathrm{i}} ; \quad>=4 \mathrm{i} A \mathrm{k}_{\mathrm{iz}}^{\mathrm{t}}(\mathrm{j}) \mathrm{T}_{\mathrm{j}} \quad\left(\mathrm{k}_{\mathrm{i}}\right)_{\mathrm{k}_{\mathrm{ix}} \mathrm{k}_{\mathrm{fx}}} \mathrm{k}_{\mathrm{iy}} \mathrm{k}_{\mathrm{fy}} ;\right. \tag{5.13}
\end{equation*}
$$

where $T_{j}\left(k_{i}\right)$ denotes the transm ission coe cient for the rough surface.
For the statistically averaged am plitude $\mathrm{T}^{\mathrm{fi}} \mathrm{E}^{\mathrm{E}}$, we obtain

$$
\begin{align*}
& \mathrm{k}_{0}^{2}<\mathrm{k}_{\mathrm{f}}^{\mathrm{T}} ; \mathrm{jj}{ }^{\mathrm{c}, \mathrm{~m}} \mathrm{k}_{\mathrm{i}} ;>^{\mathrm{E}}=\mathrm{iA} \mathrm{k}_{0}^{2} \mathrm{X}_{\mathrm{T}} \mathrm{~T}_{j}^{(0)}\left(\mathrm{k}_{\mathrm{f}}\right) \tag{5.14}
\end{align*}
$$

and

$$
\begin{equation*}
G_{z z}\left(j^{0}\right)=k_{\mathrm{k} z} \quad k_{\mathrm{kz}}^{\mathrm{E}}\left(\mathrm{j}^{0}\right): \tag{5.15}
\end{equation*}
$$

From Eqs. (5) $\overline{5} 12$ elem ent in the DW BA, as shown in Eq. (

$$
\begin{equation*}
T_{j}=T_{j}^{(0)}+{ }_{j^{0}=1 ; 2}^{x} V_{j j^{0}}^{0} T_{j^{0}}^{(0)} ; \tag{5.16}
\end{equation*}
$$

where

$$
\begin{align*}
& +{ }^{X} \quad e^{(2)} e_{j 0} e^{h} e^{\left.\frac{1}{2} q_{32}^{2}\left(j^{0}\right)\right)_{m}^{2}} \quad 1^{i}: \tag{5.17}
\end{align*}
$$

In the sam e way as we did for the re ection coe cient, using the rough-interface trans$m$ ission coe cient $T_{j}$ instead of the $s m$ ooth-interface $T_{j}^{(0)}$ in the right side of Eq. (5.1 ${ }^{-1}$ ), thus getting a self-consistent $m$ atrix equation in term $s$ of the $2 \quad 2 \mathrm{~m}$ atrioes, $\mathrm{T}, \mathrm{V}^{0}$, gives

$$
\begin{equation*}
\mathrm{T}=\mathrm{T}^{(0)}+\mathrm{V}^{0} \mathrm{~T} ; \tag{5.18}
\end{equation*}
$$

whose solution is

$$
T=\left(\begin{array}{ll}
1 & V^{0} \tag{5.19}
\end{array}\right)^{1} T^{(0)}:
$$

Sim ilarly, for the reverse interface betw een upper resonant m agnetic and low er nonm agnetic layers, we can also have the sam e solution as Eq. (5. 5 . 1 ). T he explicit expressions of ${ }^{0}$ and $\mathrm{T}^{(0)} \mathrm{m}$ atrices in Eq. ( $\left.\overline{(5)} \overline{1}{ }^{-1} \mathbf{d}\right)$ for both cases are given in A ppendix C.

For nonm agnetic interfaces, it is show $n$ in A ppendix D that Eq. (5) reduces to

$$
\begin{equation*}
T=T^{(0)} e^{\frac{1}{2}\left(k_{z} j k_{z}^{t} j\right)^{2}}{ }_{c}^{2} ; \tag{520}
\end{equation*}
$$

which has been found by V idal and V incent ${ }^{1233^{\prime}}$
VI. NUMERICALEXAMPLES FORA SINGLEMAGNETIC SURFACE

We now illustrate num erical exam ples of the above form ulae calculated for a G d surface $w$ th varying degrees of structural and $m$ agnetic roughness. W e have considered only the case where the $m$ agnetization vector is aligned along the sam ple surface in the scattering plane in order to enhance the $m$ agnetic e ect.
$F$ igure ' ${ }_{-1}^{1}$, show $s$ the $x$-ray resonant $m$ agnetic re ectivities calculated at the $G d L_{3}$-edge ( 7243 eV ) from G d surfaces w th di erent interfacial w idths for structural ( c) and magnetic
( m ) interfaces. In Fig. ${ }_{-1}^{2-1}(\mathrm{a})-(\mathrm{c})$, the interfacial width of the structural interface is larger than that of the $m$ agnetic interface, that is, $c=8 \mathrm{~A}$ and $m=3 \mathrm{~A} .0 \mathrm{n}$ the other hand, in Fig. ${ }_{1}^{2}(\mathrm{~d})-(\mathrm{f})$, the interfacial widths are reversed, that is, $\mathrm{c}=3 \mathrm{~A}$ and $\mathrm{m}=8 \mathrm{~A}$. In the
 corresponds to pure charge scattering, and ! scattering (dashed lines in the top panels of F ig. ( ${ }^{(\underline{3}) \text { ) }}$ ) to pure m agnetic scattering, and the di erences between the re ected intensities for right- ( $I_{+}$) and left- (I ) circularly polarized incident beam $s$ (circles in $F$ ig. ' ${ }_{-1}$ ) correspond to the interferences between charge and $m$ agnetic scattering.
$K$ inem atically, the re ected intensities from each scattering channels are proportional to a simple G aussian form, $\exp \left({ }^{2} q_{2}^{2}\right)$, where is the interfacial width of corresponding scattering channel, ie., c for $I_{1}, m$ for $I$, and $\frac{1}{(\underset{c}{2}+\underset{m}{2})=2}$ for ( $\left.I_{+} I\right)$. The m iddle panel of $F$ ig. 'ī-1 show s natural logarithm s of the re ectivities from rough interfaces norm alized to those from ideal system $s$ w ithout roughness as a function of the square of the wave vector, $q_{2}^{2}$, whose slopes are then equal to the squares of the interfacial widths for their corresponding scattering channels. In Fig. 'ī1-1 (b), the slopes obtained from our dynam ical calculation for the case of $\mathrm{c}=8 \mathrm{~A}$ and $\mathrm{m}=3 \mathrm{~A}$ show good agreem ent with the kinem atical results $m$ entioned above. On the other hand, in $F$ ig. $i_{1}^{\prime}(e)$, the slopes of I ! and ( $I_{+}$I) for the opposite case, $c=3 \mathrm{~A}$ and $m=8 \mathrm{~A}$, are not equal to the squares of their corresponding interfacialw idths but follow the slope of I ! at high q's.
$T$ his indicates that the kinem atical argum ent $m$ entioned above, i.e., one-to-one correspondence such as ! channel to pure $m$ agnetic scattering, is no longer valid for such a case of larger $m$ agnetic interfacial width, as shown in $F$ ig. 'ī1 (e). In other w ords, both contributions from charge and $m$ agnetic scattering should be taken into account for every scattering channel, whidh is naturally included in the dynam ical theory (such as our selfconsistent $m$ ethod). In the case shown in $F$ ig. $i_{-1}^{-1}(e)$, since the charge-scattering channel is $m$ uch stronger than the $m$ agnetic-scattering channel and also drops o much more slow ly $w$ th $q_{\text {s }}$ due to decreased roughness, there is conversion of ! polarization at larger $q$ even when the \pure" $m$ agnetic scattering has becom e negligible in the kinem atical lim it, because of $m$ agnetic scattering out of the still strong charge channel. Thus the ! and ( $I_{+} \quad$ I ) re ections will asym ptotically decay at a rate govemed by the decay of the charge channel, which is determ ined by calone.

H ow ever, it is not easy to nd a physical system where a m agnetic interfacial width is
larger than the structural one at the sam e interface, as shown in Fig. '컥 (f). Instead, such a rougher $m$ agnetic interface can occur in a m agnetic system, where a m agnetically \dead" layer exists near the top surface and so the average position of the $m$ agnetic interface $m$ ay
 ( $I_{4} \quad$ I ) (circles) show $s$ an oscillation due to a m agnetically dead layer $w$ ith its thickness of 20 A . In this case, the slopes in Fig. ${ }^{\prime}$ - 1 ( h ) follow again the kinem atical result m entioned above because the $m$ agnetic interface and the structural one are separated spatially.

As a further check on our calculations, we have calculated the re ectivity by dividing the error-function pro $l e$, as shown in the bottom panel of $F$ ig. $\overline{3}$, into $m$ any very thin
 W e found that the results using this slice $m$ ethod are exactly the sam e as those from our selfconsistent $m$ ethod assum ing $G$ aussian height distributions in $F$ ig. . $m$ ethod based on the DW BA produces very accurate results for the $x$-ray resonant $m$ agnetic re ectivity and much faster com putationally.
VII. MULTPLEMAGNETIC $\mathbb{I N}$ TERFACES

For a m ultilayer w ith m ultiple interfaces, each layer can be characterized by its dielectric susceptibility tensor in for the $n$-th layer, which can be $\quad \mathrm{m}=\mathrm{n}$ for nonm agnetic (isotropic) layers and $\mathrm{in}^{\mathrm{n}}=\mathrm{n} \quad+{ }_{\mathrm{n}}{ }^{(2)}$ form agnetic (anisotropic) layers. Foreach rough interface, we can use the self-consistent DW BA to de ne the re ection and transm ission coe cients, in the sam eway as in Sec. V, which are given by

$$
\begin{align*}
& \mathrm{R}_{\mathrm{n}}=\left(\begin{array}{ll}
\mathrm{I} & \mathrm{~V}_{\mathrm{n}}
\end{array}\right)^{1}\left(\mathbb{R}_{\mathrm{n}}^{(0)}+\mathrm{U}_{\mathrm{n}}\right)=M_{n}^{\mathrm{rt}} ; \\
& \mathrm{T}_{\mathrm{n}}=\left(\begin{array}{ll}
\mathrm{I} & \mathrm{~V}_{\mathrm{n}}^{0}
\end{array}\right)^{1} \mathrm{~T}_{\mathrm{n}}^{(0)}=\mathrm{M}_{\mathrm{n}}^{\mathrm{tt}} ; \tag{7.1}
\end{align*}
$$

where $R_{n}, T_{n}$ are the re ection and transm ission coe cients for the $n$-th rough interface, and $R_{n}^{(0)}, T_{n}^{(0)}$ are those for the corresponding sm ooth interface. $T$ he explicit expressions for $R_{n}^{(0)}, T_{n}^{(0)}, U_{n}, V_{n}$, and $V_{n}^{0} m$ atrices in Eq. (ITi) are given in A ppendix $C$, depending on whether the upper and lower layers on the $n$-th interface are nonm agnetic or magnetic layers, respectively.

By analogy w ith the recursion relation for the coupled waves derived for the sm ooth interfaces in A ppendix E (originally developed by Stepanov and Sinh ${ }^{-1-15^{\prime}}$ ), introducing $W^{\sim}{ }^{\text {pq }}$
$m$ atrioes for the rough interfaces, we $m$ ay derive the recursion relation analogous to Eq. (E-5), obtaining

$$
\begin{aligned}
& W_{n+1}^{\mathrm{tt}}=\mathscr{A}_{n}^{\sim} \mathrm{W}_{n}^{\mathrm{tt}} ;
\end{aligned}
$$

$$
\begin{align*}
& W_{n+1}^{r t}=W_{n}^{r t}+B_{n}^{r} M_{n+1}^{r t} W_{n}^{r t} ; \\
& W_{n+1}^{r r}=B_{n}^{r} M_{n+1}^{r r} ; \tag{72}
\end{align*}
$$

where $\overparen{A}_{n}$ and $\overparen{B}_{n}$ are de ned by

$$
\begin{align*}
& \widetilde{A}_{n}=M_{n+1}^{r t t} 1 \quad W_{n}^{r t}{\underset{M}{n+1}}_{r t}^{r t} ; \\
& \mathcal{B}_{n}^{r}=\mathcal{W}_{n}^{r r} 1 \quad M_{n+1}^{r t} W_{n}^{r r}{ }^{1}: \tag{7.3}
\end{align*}
$$

$F$ inally, the specular re ectivity of a magnetic multilayer w ith rough interfaces can be obtained by

$$
\begin{equation*}
R_{0}=W_{N}^{N t} T_{0}: \tag{7.4}
\end{equation*}
$$

To calculate the sum and di erence in the re ectivities for ( + ) and ( ) circularly polarized


$$
\begin{align*}
& I_{+} \quad I=2 \mathrm{Im}\left(\mathcal{W}_{N}^{\mathrm{rt}}\right)_{11}\left(\mathcal{W}_{\mathrm{N}}^{\mathrm{rt}}\right)_{12}+\left(\mathcal{W}_{\mathrm{N}}^{\mathrm{rt}}\right)_{21}\left(\tilde{W}_{\mathrm{N}}^{\mathrm{rt}}\right)_{22}{ }^{\mathrm{i}} \text {; } \tag{7.5}
\end{align*}
$$

where $\left(W_{N}^{r t}\right)_{i j}$ is the ij-elem ent of the $2 \quad 2 \mathrm{~m}$ atrix $W_{N}^{r t}$.
The above suggested approach to caloulating the e ects of roughness in multilayers on specular re ectivity is an approxim ation analogous to those used previously in several pub-
 ection coe cient (or the scattering $m$ atrix) of each interface over the interface roughness. T he com parison w ith the results of rigorous \slicing $m$ ethod" $m$ ade in Ref. '2̄Ḡ has proven that such an approxim ation works very well. A possible reason for the excellent validity of this approxim ation is that the roughness e ect is $m$ ainly displayed at greater incidence angles, where the re ection is sm all and the multiple scattering can be neglected (the total re ection am plitude is a linear sum of contributions from individual interfaces). N ote that, since we are considering the coherent scattering which involves only the statistical average of the scattering am plyde in Eq. ( $\overline{4} . \overline{1}=1$ correlations of roughness. This will not be the case with di use (o -specular) scattering
VIII. NUMERICALEXAMPLESFORMULTIPLE INTERFACES

W epresent here num ericalexam ples for $x$ ray resonant m agnetic re ectivity from $\mathrm{a} G \mathrm{~d} / \mathrm{Fe}$
 Curie tem peratures and strong interfacial coupling of Gd and Fe , these system s give rise to com plex $m$ agnetic structures depending on the layer thickness, tem perature, and applied $m$ agnetic eld 127: D ue to the advantage of $d \mathrm{~L}$ edge resonances available in the hard x-ray regim e, severalexperim entalstudies from these $G \mathrm{~d} / \mathrm{FeM}$ Ls have been perform ed using x-ray resonant $m$ agnetic re ectivity m easurem ents, 13128 A gain, we have considered only the case where the $m$ agnetization vector $\mathrm{M} \mathrm{k} \hat{\mathrm{x}}$.

W e have used the experim entally determ ined values for charge and $m$ agnetic resonant scattering am plitudes, $f_{c, m}=f_{c, m}^{0}+i_{c, m}^{\infty}$, at the resonant energy. The energy dependence of the absorption coe cient for opposite helicites, ( $E$ ), were m easured from a $[\mathrm{Gd}(51$ A ) $/ \mathrm{Fe}(34 \mathrm{~A})]_{15} \mathrm{~m}$ ultilayer, which will be discussed below as an experim ental exam ple. The edge-step norm alized $f_{c, m}^{\infty}$ were obtained from the charge and magnetic absorption coe cients, $c, m\left[c_{c}=\left({ }^{+}+\right)=2, m={ }^{+} \quad\right]$, through the optical theorem, $f_{c, m}^{\infty} / \quad c, m$. T heir absolute values w ere determ ined using the tabulated bare-atom scattering am plitudes aw ay from resonance. R ealparts w ere obtained from di erentialK ram ers $K$ ronig transform $s$ of im aginary parts. Figure ${ }_{2} \overline{4}(\mathrm{~A})$ and (b) show the charge and magnetic scattering am plitudes around the $G \mathrm{~L}_{2}$-edge obtained in such absorption $m$ easurem ents. T hese values are in good agreem ent w ith the calculated ones from the listed values of $A$ and $B$ in Eq. (3) obtained from Ref. $\bar{i}$. For consistency of the de nitions, it should be m entioned that the
 B ], respectively.

Figure 畐 show s the calculated x-ray resonant magnetic re ectivities from a $[G d(51$ A) $/ \operatorname{Fe}(34 \mathrm{~A})]_{15} \mathrm{~m}$ ultilayer for di erent incident $x$-ray energies indicated in $F$ ig. $\bar{A}_{-1} 1:$ (a) 7926 eV , (b) 7929 eV , (c) 7931 eV , and (d) 7935 eV . The lines and sym bols represent the sum and di erence in the re ected intensities for (+) and () circularly polarized incident $x$-rays, respectively, calculated using Eq. (7̄-工). Since the G d/Fe m ultilayer w as assum ed to be sandw iched betw een $N$ b bu er (100 A ) and cap (30 A ) layers, the $K$ iessig fringes betw een the m ultilayer peaks in ( $I_{+}+I$ ) intensities result from the interference of the scattering of Nb layers and thus show liltle energy dependence around the G d absonption edge. On
the other hand, ( $I_{+}$I ) intensities around the multilayer peaks show a clear energy dependence in signs and $m$ agnitudes relative to ( $I_{+}+I$ ) intensities. In Fig. 5 (a) and (d) at which energies $f_{m}^{\infty}$ becom es $m$ uch $s m$ aller than $f_{m}^{0}$, the signs and relative $m$ agnitudes of ( $I_{+} \quad I$ ) intensities follow simply the energy dependence of $f_{m}^{0}$ in $F$ ig. ${ }_{-1}^{1 / 4}(\mathrm{l})$ ), as expected in the kinem atical approxim ation $\overline{1} 9$ cannot be neglected, how ever, one can hardly expect the signs and magnitudes of ( $I_{+}$I ) intensities to be obtained directly from the values of $f_{m}^{0}$ and $f_{m}^{\infty}$ in $F$ ig. $\frac{1-4}{-1}(b)$. Therefore, quantitative analysis on $x$-ray resonant $m$ agnetic re ectivity data at the resonant energy requires accurate calculation taking into account refraction and multiple scattering e ects using dynam ical theory, such as our self-consistent m ethod presented above.

In order to study the e ect of the $m$ agnetic roughness am plitude, ( $I_{+} \quad I$ ) intensities for tw o cases, $m<c$ and $m>c$, have been calculated, as shown in F ig. ī. The The calculations for $m=c$ have been show $n$ in $F$ ig. 点. For all cases, the charge roughness am plitudes were assum ed to be $\quad c ; F e=G d=4: 7 \mathrm{~A}$ and $\quad c ; \mathrm{d}=\mathrm{Fe}=3: 6 \mathrm{~A}$. At the energy of 7935 $e V$, the intensities of ( $I_{+} \quad I$ ) around the multilayer peaks are proportional to a sim ple

 given by the kinem atical argum ent. O n the other hand, at the energy of 7929 eV where $f_{m}^{\infty}$ cannot be neglected, such a kinem atical argum ent is no longer valid. C om paring $F$ igs.
 follow a G aussian form, $\exp \left({ }^{2} q_{z}^{2}\right)$, but their signs change from negative (lled circles) to positive (open circles) values. This indicates that ( $I_{+}$I ), which is known to be the chargem agnetic interference scattering in the kinem atical theory ${ }_{r}{ }^{7}$ is sensitive even to the interference betw een charge and magnetic roughness am plitudes. However, it should be $m$ entioned again that this result cannot be reproduced by the kinem atical calculation but only by the dynam ical one presented above.

Let us now consider the case where the $m$ agnetic structure in the resonant layers $m$ ay not coincide $w$ th the chem ical structure. For exam ple, the ferrom agnetic $m$ om ents in $G d$ layers near $G d / F e$ interfaces can be induced by the ad jacent ferrom agnetic Fe layers above
 interface betw een a ferrom agnetic layer and an antiferrom agnetic layer. H ere we assum e sim ply three di erent $m$ agnetization depth pro les in the $G$ d layers of a G d/Fe m ultilayer,
as show in $F$ ig. ini: uniform $m$ agnetization (A), ferrom agnetic $m$ om ents only near the $G d / F e$ interfaces (B), ferrom agnetic $m$ om ents near the centers of $G d$ layers betw een $m$ agnetically dead layers (C).

Figure' $\overline{-1}$, show s the results of calculations of $x$-ray resonant $m$ agnetic re ectivities from $[\mathrm{Gd}(51 \mathrm{~A}) / \mathrm{Fe}(34 \mathrm{~A})]_{15} \mathrm{M}$ Lsw th the di erent m agnetic structures ofF ig. ${ }_{-1} \mathrm{~T}_{1}$. W e assum ed all $m$ agnetic roughness amplitudes of $m=4.2 \mathrm{~A}$ (e ectively sameas $c$ ) and the photon energy of $\mathrm{E}=7929 \mathrm{eV}$. In F igs. $\mathrm{i}_{1}(\mathrm{~B})-(\mathrm{c}), \mathrm{G}$ d layers were assum ed to be $m$ agnetized only near the $\mathrm{Gd} / \mathrm{Fe}$ interfaces [m odel (B)], and the thickness of each magnetized layer was assum ed to be 4.6 A (a), 8.4 A (b), and 12.8 A (c). On the other hand, in Fig. ${ }_{-1}^{\mathrm{i}}$ (d)-( f$)$, G d layers were assum ed to be $m$ agnetized in the $m$ iddle of each $G d$ layer and sandw iched between $m$ agnetically dead layers [m odel (C)], and the thickness of each dead layer was assum ed to be 4.6 A (d), 8.4 A (e), and 12.8 A (f).
 ( $I_{+}$I ) intensities in $F$ ig. 'ision form odels (B) and (C) show no suppression in peak intensities due to the charge-m agnetic interference, as discussed above. This may be ascribed to a spatial separation between the charge and magnetic interfaces in models (B) and (C), as shown in Fig. ${ }^{2}$ in.

In addition, the signs and relative $m$ agnitudes of ( $I_{+} \quad I$ ) intensities at the $m$ ultilayer peaks change rem ankably as the thidknesses of $m$ agnetized layers change. In general, the peak intensities of the ( $m+n$ ) th order M L peak and its m ultiple orders are weak com pared to other peak intensities when the thidkness ratio between two constituent layers is $n=m$. For example, in our $\operatorname{Gd}(51 \mathrm{~A}) / \mathrm{Fe}(34 \mathrm{~A}) \mathrm{multilayer}$, the fth peak corresponds to such a suppressed peak. Therefore, di erent thicknesses of $m$ agnetic layers readily change the order of the suppressed peak in ( $I_{+}$I) intensities, as shown in Fig. ' $8-1$. . On the other hand,
 opposite each other, because their m agnetic stnuctures are exactly reversed.
IX. EXPERIMENTS
$X$-ray resonant $m$ agnetic re ectivities were $m$ easured from an $\operatorname{Fe}(34 A) /[G d(51 A) / F e(34$ A) $l_{15}$ m ultilayer. The multilayer was sputtered onto a Si substrate using Nb bu er (100 A ) and cap ( 30 A ) layers. $S Q U \mathbb{D}$ m agnetom etry and XMCD m easurem ents show that the
m ultilayer couples antiferrom agnetically at the $\mathrm{Gd} / \mathrm{Fe}$ interfaces and have coercive elds < 500 e at 300 K . X -ray m easurem ents were perform ed at sector 4 of the A dvanced P hoton Source at A rgonne N ational Laboratory. U ndulator radiation was m onochrom atized with double Si(111) crystals and its polarization converted from linear to circular with a diam ond (111) quarterw ave plate operated in B ragg transm ission geom etry $y^{\prime 29}$ 'T The sam ple was placed in a $B=2: 1 \mathrm{kG}$ eld parallel to its surface and in the scattering plane. Specular magnetic re ectivity was measured at room tem perature with a photon energy near the $\mathrm{Gd}_{\mathrm{d}}$ resonance (7929 eV ) across multilayer B ragg peaks by sw itching the helicity of the incident radiation at each scattering vector $q_{z}=(4=) \sin$, with being the grazing incidence angle.

Figure ${ }_{-1}^{1}{ }_{-1}$ show s specular re ectivity curves obtained by adding $\left[(a),\left(I_{+}+I\right)\right]$ and subtracting [(b), ( $\left.I_{+} \quad I\right)$ ] re ected intensities for opposite helicites of the incom ing $x$ rays. Symbols represent $m$ easurem ents and solid lines represent the ts calculated using Eq. (ī- ${ }_{-1}$ ). From the $t$ for ( $I_{+}+I$ ) intensities, we obtained the layer thidknesses $d_{G d}=50: 74 \quad 0: 09 \mathrm{~A}$ and $d_{f e}=33: 98 \quad 0: 09 \mathrm{~A}$, and the roughness am plitudes of charge interfaces c;Fe-Gd $=4: 7 \quad 0: 1 \mathrm{~A}$ and $c_{;} ; \mathrm{Gd}=\mathrm{Fe}=3: 6 \quad 0: 1 \mathrm{~A}$. From the t for ( $\mathrm{I}_{+} \quad \mathrm{I}$ ) intensities, we found that the Gd layers were fully $m$ agnetized only near the $\mathrm{Gd} / \mathrm{Fe}$ interfaces at room tem perature, which is above the bulk $T_{c}$ of Gd . This magnetization is induced by a strong antiferrom agnetic exchange interaction w the the agnetically ordered Fe layers? From the best $t$, the thidkness of the ferrom agnetic $G d$ layer was estim ated to be $4: 5 \quad 0: 3$ A , which is consistent w th our previous work 1121 M agnetic roughness am plitudes for $\mathrm{Gd} / \mathrm{Fe}$ ( $\mathrm{Fe} / \mathrm{Gd}$ ) and G d-ferrom agnetic/G d-param agnetic interfaces were estim ated to be $4: 2 \quad 0: 1$ A and $4: 6 \quad 0: 1 \mathrm{~A}$, respectively.

## X. CONCLUSIONS

The formulae for $x$-ray resonant $m$ agnetic specular re ectivity have been derived for both single and $m$ ultiple interfaces using the self-consistent $m$ ethod in the fram ew ork of the distorted w ave B om approxim ation (DW BA ).For this puppose, we have de ned a structural and a $m$ agnetic interface to represent the actual interfaces. The well-known $\mathrm{Nevot}-\mathrm{C}$ roce expression for the x-ray specular re ectivity from a rough surface has been generalized and exam ined for the case of a magnetically rough surface. The form alism has been generalized
to the case of $m$ ultiple interfaces, as in the case of thin $\mathrm{m} s$ or $m$ ultilayers. Num erical illustrations have been given for typical exam ples of each of these system s and com pared w ith the experim ental data from a Gd/Fe multilayer. W e have also presented the explicit expressions in the sm all-angle approxim ation, which are readily applicable to transition$m$ etal and rare-earth $L$-edge resonant $m$ agnetic re ectivities. The code for the calculations in this paper is also available in $C$ language by em ailing to $D R$. (dineeaps.ani.govi).

A cknow ledgm ents

W ork at A rgonne is supported by the U S.DOE, O œ of B asic Energy Sciences, under C ontract N O. W -31-109 Eng -38.

APPENDIXA:EXPLICIT EXPRESSIONSFOR R ${ }^{(0)}, \mathrm{T}_{\mathrm{j}}{ }^{(0)} \mathrm{USING} 2 \quad 2$ MATRIX FORMULAE

To calculate the explicit expressions for $R^{(0)}$ and $T_{j}^{(0)}$ in Eq. (44.4), we follow Stepanov and Sinha's approachis' developed for $m$ agnetic resonant re ections from ideally sm ooth interfaces. The electric eld $\mathrm{E}_{\mathrm{z}<0}(\mathrm{r})$ inside the m agnetic m edium w ith a dielectric susceptibility tensor given by Eq. ( $\overline{1}_{-}^{\overline{-}} \mathbf{-}$ ) can be represented as

$$
\begin{equation*}
E_{z<0}(r)=E e^{i k_{0} u z+i k_{0} \cos \mathrm{i}^{\mathrm{x}}} ; \tag{A1}
\end{equation*}
$$

where $i$ is the incidence angle, as shown in $F$ ig. 1. The param eter $u$ can be a com plex num ber due to absonption or total re ection. Substituting this in the wave equation Eq.


$$
\begin{equation*}
\left.x{ }_{\left(\sin ^{2} i\right.} u^{2}\right)+n n+\quad{ }^{i}=0 ; \tag{A2}
\end{equation*}
$$

where $\mathrm{n}=\mathrm{k}=\mathrm{k}_{0}$, i.e., $\mathrm{n}_{\mathrm{x}}=\cos$ i, $\mathrm{n}_{\mathrm{y}}=0$, and $\mathrm{n}_{\mathrm{z}}=\mathrm{u}$.
Ifwe consider the case where the $m$ agnetization vector is aligned along the sam ple surface in the scattering plane, i.e., $M \mathrm{k} \&$ in F ig. 1 , the tensor of a resonant $m$ agnetic $m$ edium can be w ritten from Eq. (
where

$$
\begin{equation*}
{ }_{1}=\frac{4}{\mathrm{k}_{0}^{2}} 0(x) \mathrm{x}_{0}+\frac{4}{\mathrm{k}_{0}^{2}} \mathrm{An}_{\mathrm{m}}(x) ; \quad \mathrm{B}^{0}=\frac{4}{\mathrm{k}_{0}^{2}} \mathrm{Bn}_{\mathrm{m}}(x) \mathrm{M}_{\mathrm{x}} ; \mathrm{C}^{0}=\frac{4}{\mathrm{k}_{0}^{2}} \mathrm{Cn}_{\mathrm{m}}(x) \mathrm{M}_{\mathrm{x}}^{2}: \tag{A4}
\end{equation*}
$$

A ssum ing that the incidence angle ${ }_{i}$ is small $\left(\sin _{i} \quad i \quad 1\right.$ and $n_{x}=\cos { }_{i} \quad 1$ ) and even at the resonance remain small (j j 1), and inserting Eq. ( $\left.\bar{A} \overline{\bar{S}_{1}^{\prime}}\right)$ into Eq. ( $\left.\bar{A} \overline{\mathrm{~A}} \overline{\mathrm{~L}} \mathrm{j}^{\prime}\right)$, the dispersion equation for a nontrivial solution of Eq. (Ā) can be then approxim ated by

and the respective roots are $u^{(1 ; 2 ; 3 ; 4)}=\frac{q}{i_{i}^{2}+1 \quad B^{0}}$. Two roots of these $u^{(j)}$ 's w ith Im $\left[u^{(1 ; 2)}\right]>0$ and the other two roots with Im $\left[u^{(3 ; 4)}\right]<0$ correspond to transm itted and
 ( $\mathrm{j}=1$; :::;4)

$$
\begin{equation*}
E_{z}^{(j)}=\frac{2_{i}^{2}+1 u^{(j) 2}}{i B^{0}} E_{y}^{(j)} ; E_{x}^{(j)}=u^{(j)} \frac{i_{i}^{2}+1 u^{(j) 2}}{i B^{0}} E_{y}^{(j)} ; E_{y}^{(j)}=E^{(j)}: \tag{A6}
\end{equation*}
$$

A nd if we denote

$$
\begin{align*}
& u^{(1)}=\frac{q}{{ }_{i}^{2}+1_{1}+B^{0}} \quad u_{4} ; u^{(2)}=\frac{q}{i_{i}^{2}+1} B^{0} \quad u ; \\
& u^{(3)}=u_{4} ; u^{(4)}=\quad u ; \tag{A7}
\end{align*}
$$

we m ay then w rite

$$
\begin{align*}
& E_{z}^{(1)}=i E^{(1)} ; E_{z}^{(2)}=i E^{(2)} ; E_{z}^{(3)}=i E^{(3)} ; E_{z}^{(4)}=i E^{(4)} ; \\
& E_{x}^{(j)}=u u^{(j)} E_{z}^{(j)} \quad(j=1 ;:: ; 4): \tag{A8}
\end{align*}
$$

Since $j^{(j)}{ }^{(j)} \quad 1, E_{x}^{(j)}$ can be neglected, then the polarizations of the waves $e^{(j)}$ in the $m$ agnetic resonant $m$ edium can be reduced to the circular polarizations

$$
\begin{array}{ll}
e^{(j)} \quad E_{y}^{(j)} A+E_{z}^{(j)} A & (\hat{y}=e ; \hat{Z} \quad \text { e } ; \\
e^{(1)}= & e+i e=e^{(3)} ; \quad e^{(2)}=e \quad \text { ie }=e^{(4)}: \tag{A9}
\end{array}
$$

If the wave eld $\mathrm{E}_{\mathrm{z}>0}(\mathrm{r})$ w ith the incident and specularly re ected waves inside the non$m$ agnetic (isotropic) m edium can be represented as

$$
\begin{equation*}
E_{z>0}(r)=E_{0} e^{i k_{0} u_{0} z}+E_{R} e^{i k_{0} u_{0} z} e^{i k_{0} \cos i_{i} x} ; \quad u_{0}=\frac{q}{i_{i}^{2}+0} ; \tag{A10}
\end{equation*}
$$

 be satis ed for the lateral com ponents $\mathrm{E}_{\mathrm{k}}$ and $\mathrm{H}_{\mathrm{k}}$ of electric elds and magnetic elds, respectively. Since $H / \widehat{k} E$ ], this gives

$$
\begin{align*}
& u_{0} E_{0} \quad u_{0} E_{R}=X_{x}^{(j)}  \tag{A11}\\
& E_{0}+E_{R}={ }^{X^{j}} E_{y}^{(j)} \\
& u_{0} E_{0} \quad u_{b} E_{R}=u^{j(j)} X^{j} E_{y}^{(j)} \\
& E_{0}+E_{R}=X_{j}^{\left(u^{(j)} E_{x}^{(j)}+n_{x} E_{z}^{(j)}\right) \quad X_{j} E_{z}^{(j)} ; ~ ; ~}
\end{align*}
$$

where the approxim ation in the last equation was obtained by $j^{(j)} j \quad 1$ and $n_{x} \quad 1$. U sing Eqs. $\left.(\bar{A}-\bar{\sigma})-\left(\bar{A} \bar{A}_{-}^{-}\right)^{\prime}\right)$, the above equations can be expressed in the $4 \quad 4 \mathrm{~m}$ atrix form

Representing the waves as the vectors $T_{0}=\left(E_{0} ; E_{0}\right), R_{0}=\left(E_{R} ; E_{R}\right), T_{1}=\left(E^{(1)} ; E^{(2)}\right)$, and $R_{1}=\left(E^{(3)} ; \mathrm{E}^{(4)}\right)$, the 44 m atrioes in Eq. ${ }^{\prime \prime}(\bar{A} \overline{1} 2 \underline{2})$ can be reduced into four $2 \quad 2$ blocks
where $X^{t t}, X^{t r}, X^{\mathrm{rt}}, X^{\mathrm{rr}}$ can be obtained by multiplying the inverse of the $4 \quad 4 \mathrm{~m}$ atrix at the left side of Eq. ( $\left.\bar{A}_{-}^{-1} \underline{1}^{-2}\right)$ onto the both sides. Since the re ected waves inside the m edium vanish for a single surface, $\mathrm{E}^{(3)}=\mathrm{E}^{(4)}=0$ [i.e., $\mathrm{R}_{1}=(0 ; 0)$ ], the \unknown" waves $\mathrm{R}_{0}$ and $\mathrm{T}_{1}$ in Eq. ( $\left(\bar{A} \overline{\mathrm{~A}} \overline{1}_{-1} \mathrm{~S}_{1}\right)$ can be expressed via the $\backslash$ known" waves $\mathrm{T}_{0}$ and $\mathrm{R}_{1}$ as
where

$$
\begin{align*}
& M^{t t}=\left(X^{t t}\right)^{1} ; M^{t r}=\left(X^{t t}\right)^{1} X^{t r} ; \\
& M^{r t}=X^{r t}\left(X^{t t}\right)^{1} ; M^{r r}=X^{r r} X^{r t}\left(X^{t t}\right)^{1} X^{t r}: \tag{A15}
\end{align*}
$$



$$
\begin{aligned}
& M_{n!r}^{\text {tt }}=\sum_{0}^{\begin{array}{c}
B \\
\frac{u_{0}}{u_{0}+u_{+}}
\end{array} \frac{1}{\frac{u_{0}}{u_{0}+u_{+}}} \underset{A}{C}=T_{j}^{(0)}\left(k_{i}\right) ; ~} \\
& M_{n!r}^{\operatorname{tr}}=\begin{array}{c}
\frac{u_{+} u_{0}}{u_{0}+u_{+}} \quad 0 \\
0 \quad \frac{u \quad u_{0}}{u_{0}+u}
\end{array}
\end{aligned}
$$

where the ij-elem ents of $M{ }^{p q} m$ atrices are de ned by $F i g$. 10, and the subscript $n!r$ represents the incidence from a nonm agnetic $m$ edium into a resonant $m$ agnetic one. From the de nition of $M^{p q} m$ atrioes in Eq. $\left(\underline{(1-\overline{1}} \overline{1} \bar{L}_{1}\right), R^{(0)}\left(k_{i}\right)$ and $T_{j}^{(0)}\left(k_{i}\right)$ correspond to $M_{n!r}^{r t}$ and $M_{n!r}^{t}, r e s p e c t i v e l y . ~ F o r ~ t h e ~ t i m ~ e-r e v e r s e d ~ w a v e s ~ i n c i d e n t ~ w i t h ~ v e c t o r ~\left(~\left(~ k_{f}\right)\right.$, scattering angle f , and polarization, $\mathrm{M}_{\mathrm{n}!}^{\mathrm{pq}} \mathrm{r}_{\mathrm{r}}\left(\mathrm{k}_{\mathrm{f}}\right) \mathrm{m}$ atrioes are sam e as the case of $\left(\mathrm{k}_{\mathrm{i}}\right.$; $)$ but replacing $i$


$$
\begin{align*}
M_{n!r}^{p q}\left(k_{f}\right) & =M_{n!r}^{p q}\left(k_{i} ; i \$ \quad \text { i); } \quad(p q=t t ; t r ; r t ; r r) ;\right. \\
T_{j}^{(0)}\left(k_{f}\right) & =T_{j}^{(0)}\left(k_{i} ; i \$ \quad \text { i); } R^{(0)}\left(k_{f}\right)=R^{(0)}\left(k_{i} ; i \$ \quad\right. \text { i): }\right. \tag{A17}
\end{align*}
$$

For com pleteness, let us now consider the reverse case where a wave is incident \from " a m agnetic (anisotropic) m edium w th $=1+{ }^{(2)} \backslash$ into" a nonm agnetic one w th
$=0 \quad . \quad$ The explicit form $s$ of $M{ }_{r!}^{p q} n$ atrioes can be evaluated by starting $w$ ith

 be obtained straightforw ardly by

$$
\begin{align*}
& M_{r!n}^{u t}=T T_{j}^{(0)}\left(k_{i}\right)=M_{n!r}^{r r} ; M_{r!n}^{r r}=M_{n!r}^{r t} ; \\
& M_{r!n}^{r t}=R_{j j^{0}}^{(0)}\left(k_{i}\right)=M_{n!r}^{t r} ; M_{r!n}^{r r}=M_{n!r}^{t t} ; \tag{A18}
\end{align*}
$$

$w$ here the subscript $r$ ! $n$ denotes the incidence from a resonant $m$ agnetic $m$ edium into a nonm agnetic one. In the same way as in Eq. ( $\left.\overline{\mathbb{A}} \overline{1}^{-1}-1\right)$, the $M{ }_{r!}^{p q} n\left(k_{f}\right) m$ atrioes for the

$F$ inally, let us also consider the $m$ agnetic $m$ agnetic (resonant-resonant) interface betw een
 layers. By em ploying the $4 \quad 4 \mathrm{~m}$ atrices involving resonant $m$ agnetic $m$ edium to both sides of Eq. ( $\bar{A} \overline{1} \overline{1} \overline{2})$ ), the explicit expressions of $M{ }_{r}^{p q}$ r can be given by
 $M \underset{r!}{p q} m$ atriaes for the $m$ agneticm agnetic interfaces are applicable to the nonm agneticnonm agnetic (nonresonant-nonresonant) interfaces sim ply by setting $B_{u p ; d w}^{0}$ to be zero.

APPENDIX B:EVALUATION OFTHEMATRIXELEMENTSINVOLVING

To evaluate the $m$ atrix elem ent in Eqs. (1. $\left.\overline{1} \overline{1} \mathbf{T}_{1}\right)$ and ( $\left.\overline{5} . \overline{1} \overline{2}^{\prime}\right)$, we assum e that $0=0$ in Eq.
 can be evaluated from Eqs. ( $\overline{4}-\bar{A})$ and ( $\overline{4} .1$

$$
\begin{align*}
& k_{0}^{2}<k_{f}^{T} ; j^{(0)} \mathcal{F}^{i}(r)>=A k_{0}^{2} k_{i x} k_{f x} k_{i y} k_{f y}{ }_{j}^{X} T_{j}^{(0)}\left(k_{f}\right) \\
& \text { X } e_{j}\left(1+{ }^{(2)}\right) e^{Z}{ }_{1} d z e^{i\left(k_{f z}^{t}(j) k_{i z}\right) z} \text {; } \\
& =\mathrm{iA} \mathrm{k}_{0}^{2} \mathrm{k}_{\mathrm{ix}} \mathrm{k}_{\mathrm{fx}} \quad \mathrm{k}_{\mathrm{iy}} \mathrm{k}_{\mathrm{f} y} \\
& { }^{x} \frac{T_{j}^{(0)}\left(k_{f}\right)}{k_{f z}^{t}(j)}{ }^{\mathrm{k}} \mathrm{k}_{\mathrm{fz}} e_{j}\left({ }_{1}+{ }^{(2)}\right) \mathrm{e}: \tag{B1}
\end{align*}
$$

In order to evaluate the explicit expression for the above equation, let us now consider the case where the incidence angle $i$ is $s m$ all and $M \quad k \hat{x}$, as discussed in A ppendix A. In this case, $e_{j}=e \quad$ ie and $k_{f z}^{t}(j)=k_{0} u$, where the upper and lower signs correspond

polarization-dependent term s are evaluated by

$$
\begin{align*}
& { }^{x} e_{j}\left(1+{ }^{(2)}\right) e=1\left(e_{j} \theta\right)+\left(e_{j} \quad \theta\right)_{x}^{(2)}{ }_{M} \quad(x) \\
& \begin{array}{llll} 
\\
1_{1}+i^{(2)}=u_{+}^{2} & u_{0}^{2} ; & \text { for } j=1 ; & = \\
i_{1}^{(2)}=u^{2} & u_{0}^{2} ; & \text { for } j=2 ; & = \\
i_{1}+{ }^{(2)}= & i\left(u_{+}^{2}\right. & \left.u_{0}^{2}\right) ; & \text { for } j=1 ;
\end{array} \tag{B2}
\end{align*}
$$

where $u_{0}=i$ when $0=0$ in Eq. ( $\left.\bar{A} \mathcal{A}_{-1}^{-1} 0^{\prime}\right)$. The explicit form of $2 \quad 2 \mathrm{matrix} \mathrm{T}_{j}^{(0)}\left(\mathrm{k}_{\mathrm{f}}\right)$ can be obtained from $M_{n!r}^{u t}$ in Eq. ( $\bar{A}-1$ ( $\sigma$ ) by replacing $i b y(i)$. Then, the $m$ atrix elem ent in Eq. ( $\overline{4} \overline{1} \overline{5}$ ) $)$ can be expressed by $2 \quad 2 \mathrm{~m}$ atrix in term s of the polarizations of incident and outgoing beam $s$, and , as follow s:

$$
\begin{align*}
& k_{0}^{2}<k_{f}^{T} ; j^{(0)} \mathcal{F}^{i}(r)>=\operatorname{la}_{0}^{2} k_{0}^{2} k_{\mathrm{ix}} k_{f x} k_{\text {iy }} k_{f y} \frac{2 u_{0}}{k_{0}\left(u_{+}+u_{0}\right)\left(u_{1}+u_{0}\right)} \\
& \stackrel{B}{Q} \quad u_{+} u \quad \text { un iun }\left(u_{+} \quad u\right) \underset{A}{C} \text {; } \\
& i u_{0}\left(u_{+} \quad u\right) \quad u_{+} u \quad u_{0}^{2} \\
& =2 i A k_{i z} R^{(0)}\left(k_{i}\right) k_{\mathrm{ix}} \mathrm{k}_{\mathrm{fx}} \mathrm{k}_{\mathrm{iy}} \mathrm{k}_{\mathrm{fy}} \text {; } \tag{B3}
\end{align*}
$$

 in Eq. ( $\left.\bar{B}-\overline{3}]^{\prime}\right)$ is applicable for the case w ith $0 \in 0$ although the calculation for $z>0$ should


For the transm ission coe cient, the $m$ atrix elem ent in Eq. ( 5


$$
\begin{aligned}
& \text { X } \left.e\left(1+{ }^{(2)}\right) e_{j^{0}}{ }_{1}^{Z} d z e^{i\left(k_{f z}\right.} k_{i z}^{t}\left(j^{0}\right)\right) z ; \\
& =\mathrm{iA} \mathrm{k}_{0}^{2} \mathrm{k}_{\mathrm{ix}} \mathrm{k}_{\mathrm{fx}} \mathrm{k}_{\mathrm{iy}} \mathrm{k}_{\mathrm{fy}}
\end{aligned}
$$

where the vector eld $E\left(k_{i} ;\right)$ in Eq. (5.d) has been used for the state $\mathrm{k}_{\mathrm{i}}$; $>$ instead of


the polarizations of incident and transm itted beam $s$, and $j$, as follow s:

$$
\begin{align*}
& =4 i A k_{i z}^{t}(j) k_{i x} k_{f x} k_{i y} k_{f y} \frac{B}{B_{\mathrm{i}}} \frac{u_{0}}{u_{+}+u_{0}} \frac{i u_{0}}{u_{+}+u_{0}} C \text { C } \\
& =4 i A k_{i z}^{t}(j) T_{j}^{(0)}\left(k_{i}\right) k_{i x} k_{f x} k_{i y} k_{f y} ; \tag{B5}
\end{align*}
$$

 applicable for the case w ith 0 w ithout loss of generality.

APPEND IX C:EXPLICIT EXPRESSIONSFOR ROUGH-TNTEREACEMPqMATRICES

For the interface betw een upper nonm agnetic ( = 0 ) and lower resonant magnetic $\left(\quad=1+{ }^{(2)}\right)$ layers, the explicit expressions of the rough-interface $M_{n!}^{p q}{ }_{r} m$ atrioes can be given by

$$
\begin{align*}
& \mathbb{M}_{n!r}^{r t}=R_{n!r}=\left(\begin{array}{ll}
( & V_{n!r}
\end{array}\right)^{1}\left(\mathbb{R}_{n!r}^{(0)}+U_{n!r}\right) ; \\
& M_{n!r}^{\sim}=T_{n!r}=\left(\begin{array}{ll}
I & V_{n!r}^{0}
\end{array}\right)^{1} T_{n!r}^{(0)} ; \tag{C1}
\end{align*}
$$

where, from Eqs. ( $\overline{5}$.

$$
\begin{aligned}
& 0 \quad D^{(1)}+D_{2}^{(1)}+D_{3}^{(1)} D^{(1)} \\
& \text { i } \frac{D_{1}{ }^{(1)}+D_{2}{ }^{(1)}}{u_{+}^{2} u_{0}^{2}} \quad \frac{D_{3}{ }^{(1)} D_{4}{ }^{1}{ }^{1}}{u^{2} u_{0}^{2}}
\end{aligned}
$$

$$
\begin{aligned}
& \frac{D_{1}^{(1)}+D_{2}^{(1)}}{u_{+}^{2}+u_{0}^{2}}+\frac{D_{3}^{(1)} D_{4}^{(1)}}{u^{2} u_{0}^{2}}
\end{aligned}
$$

and

$$
\begin{align*}
& \left.\left.D_{1}^{( }\right)=\left(\begin{array}{ll}
1 & \left.0) e^{\frac{k_{0}^{2}}{2}\left(u_{+}\right.} u_{0}\right)^{2}{ }_{c}^{2}
\end{array} ; D_{2}^{1}\right)=B^{0} e^{\frac{k_{0}^{2}}{2}\left(u_{+}\right.} u_{0}\right)^{2}{ }_{m}^{2} ; \\
& \left.\left.\left.\left.D_{3}^{( }\right)=\left(\begin{array}{ll}
1 & 0
\end{array}\right) e^{\frac{k_{0}^{2}}{2}(u} u_{0}\right)^{2}{ }_{c}^{2} ; D_{4}^{1}\right)=B^{0} e^{\frac{k_{0}^{2}}{2}(u} u_{0}\right)^{2}{ }_{m}^{2} \tag{C3}
\end{align*}
$$

 and $u=\frac{q}{i_{i}^{2}+1 \quad B^{0}}$.

For the reversed interface betw een upper $m$ agnetic (resonant) and lower nonm agnetic layers, $M_{r}{ }_{r!}^{p q} m$ atrioes can be also given by

$$
\begin{align*}
& M_{r!n}^{r t}=R_{r!n}=\binom{I}{V_{r!n}}^{1}\left(R_{r!n}^{(0)}+U_{r!n}\right) ; \\
& M_{r!n}^{t t}=T_{r!n}=\left(\begin{array}{l}
I
\end{array} V_{r!n}^{0}\right)^{1} T_{r!n}^{(0)} ; \tag{C4}
\end{align*}
$$

where

$$
\begin{aligned}
& \text { I } \quad V_{r!n}=I \quad V_{n!~}^{0} ; \quad I \quad V_{r!n}^{0}=I_{1} \quad V_{n!r} ;
\end{aligned}
$$

In the sam e way as Eq. ( $(\bar{A} \overline{1} \overline{1} \bar{q})$, other $M^{\sim}{ }^{p q} m$ atrioes can be given by

$$
\begin{equation*}
\mathcal{M}_{n!r}^{\operatorname{tr}}=M_{r!n}^{r t} ; M_{n!r}^{r r}=M_{r!n}^{\mu t} ; M_{r!n}^{r r}=M_{n!r}^{r t} ; M_{r!n}^{r r}=M_{n!r}^{t t} \text { : } \tag{C6}
\end{equation*}
$$

Finally, for the $m$ agnetic $m$ agnetic (resonant-resonant) interface betw een upper resonant
 layers, $M \underset{r}{\sim}{ }_{r}^{p q} m$ atrioes can be also given by

$$
\begin{align*}
& M_{r!r}^{r t}=R_{r!r}=\left(\begin{array}{ll}
( & V_{r!r}
\end{array}\right)^{1}\left(R_{r!r}^{(0)}+U_{r!r}\right) ; \\
& M_{r!r}^{u t}=T_{r!r}=\binom{I}{V_{r!r}^{0}}^{1} T_{r!r}^{(0)} ; \tag{C7}
\end{align*}
$$

where
and

$$
\begin{align*}
& \left.\left.\left.D_{5}^{( }\right)=\left(\begin{array}{ll}
d w & u p_{1} \\
1 & 1
\end{array}\right) e^{\frac{k_{0}^{2}}{2}\left(u_{+}^{d w}\right.} u_{+}^{u p}\right)^{2}{ }_{c}^{2} ; D_{6}^{(1)}=\left(B_{d w}^{0} \quad B_{u p}^{0}\right) e^{\frac{k_{0}^{2}}{2}\left(u_{+}^{d w}\right.} u_{+}^{u p}\right)^{2}{ }_{m}^{2}
\end{align*} ;
$$

and ( $I \quad V_{r!~ r}^{0}$ ) corresponds to ( $I \quad V_{r!}$ ) when switching the upper and lower layers, and
 $\left.\left(u^{u p}\right)^{2}\right]=2$ and $\left(B_{d w}^{0} \quad B_{u p}^{0}\right)=\left[\left(u_{+}^{d w}\right)^{2} \quad\left(u^{d w}\right)^{2}\right]=2 \quad\left[\left(u_{+}^{u p}\right)^{2} \quad\left(u^{u p}\right)^{2}\right]=2$ can be used from

 upper and lower layers. $W$ e should $m$ ention again that these rough-interface $M{ }^{\sim}{ }^{\mathrm{pq}} \mathrm{m}$ atrices for the $m$ agnetic m agnetic (resonant-resonant) interfaces can be reduced to the cases for the nonm agnetic-nonm agnetic (nonresonant-nonresonant) interfaces by setting $B_{u p ; d w}^{0}$ to be zero.

APPENDIX D: SOLUTIONS OF SELF-CONSISTENT MATRIX EQUATIONS FOR NONMAGNETIC $\mathbb{I N} T E R F A C E S$

For nonm agnetic interfaces $(\mathbb{M} j=0)$ and ! polarization, sim ply

$$
\begin{equation*}
u_{+}=u=\frac{q}{\bar{i}+{ }_{1}^{2}}=\mathrm{k}_{\mathrm{z}}^{\mathrm{t}} \dot{\mathrm{j}} \mathrm{k}_{0}: \tag{D1}
\end{equation*}
$$

 self-consistent solution for the re ection coe cient ( $\mathrm{k}_{\mathrm{f}}=\mathrm{k}_{\mathrm{i}}^{\mathrm{r}}$ and ${ }_{i}={ }_{f}$ ) in Eq. (5.a) can be reduced to a scalar as

$$
R=\left(\begin{array}{ll}
1 & V \tag{D2}
\end{array}\right)^{1}\left(R^{(0)}+U\right) ;
$$

where

$$
\begin{align*}
& U=\frac{k_{z} j \quad j_{z}^{t} j}{k_{z} j+k_{z}^{t} j} e^{\frac{1}{2}\left(k_{z} j+k_{z}^{t}\right)^{2}{ }_{c}^{2}} 1 \text {; }  \tag{D3}\\
& R^{(0)}=\frac{\mathrm{k}_{z} j \quad j_{z}^{\mathrm{t}} j}{\mathrm{k}_{\mathrm{z}} j+\mathrm{k}_{\mathrm{z}}^{\mathrm{t}} j^{\prime}} \\
& V=1 \quad e^{\frac{1}{2}\left(k_{z} j k_{z}^{t}\right)^{2}{ }_{c}^{2} ;}
\end{align*}
$$

and $k_{f z}^{t}=k_{z}^{t} j$ and $k_{i z}=k_{\mathrm{iz}}^{\mathrm{t}}=\quad k_{z} j$. Then, we obtain
which is consistent w ith the $N$ evot-C roce form ${ }^{121} 1$

Sim ilarly, the self-consistent solution for the transm ission coe cient in Eq. (5. ${ }^{-19}{ }^{\prime}{ }^{\prime}$ can be reduced into a scalar as

$$
\begin{equation*}
T_{( },{ }_{j=1 ; 2}^{x} T_{j}={\underset{j=1 ; 2}{x}\left(1 \quad V^{0}\right)^{1} T_{j}^{(0)} ; ~ ; ~ ; ~}_{j=1} \tag{D5}
\end{equation*}
$$

where

$$
\begin{align*}
\mathrm{V}^{0} & =1 \quad e^{\left.\frac{1}{2}\left(\mathrm{k}_{z} j j_{z}^{\mathrm{t}}\right)^{2}\right)_{c}^{2}} ; \\
\mathrm{T}_{1}^{(0)} & =\mathrm{T}_{2}^{(0)}=\frac{\mathrm{k}_{\mathrm{z}} j}{\mathrm{k}_{\mathrm{z}} j+\mathrm{k}_{\mathrm{z}}^{\mathrm{t}} j} ; \tag{D6}
\end{align*}
$$

Then,

$$
\begin{equation*}
T=\frac{2 k_{z} j}{k_{z} j+j k_{z}^{t} j} e^{\frac{1}{2}\left(k_{z} j k_{z}^{t} j\right)^{2}{ }_{c}^{2}}=T^{(0)} e^{\frac{1}{2}\left(k_{z} j k_{z}^{t} j\right)^{2}}{ }_{c}^{2} ; \tag{D7}
\end{equation*}
$$

which is consistent w ith the V idal-V incent form

APPENDIX E:RECURSIVE2 2 MATRIX FORMULAE FORMULTIPLE $\mathbb{I N}-$ terfaces

For multiple interfaces, additional phase di erences between di erent interfaces should be taken into account to extend the results for a single interface in A ppendix A. Follow ing Ref. 1 from Eq. ( $\bar{A}-15$ ) as

$$
\begin{equation*}
M_{n+1}^{\mathrm{tt}}=M^{\mathrm{tt}} F_{\mathrm{n}}{ }^{1} ; M_{\mathrm{n}+1}^{\mathrm{tr}}=M{ }^{\mathrm{tr}} ; \mathrm{M}_{\mathrm{n}+1}^{\mathrm{rt}}=F_{\mathrm{n}}{ }^{1} M^{r t} F_{\mathrm{n}}{ }^{1} ; M_{\mathrm{n}+1}^{\mathrm{rr}}=F_{\mathrm{n}}{ }^{1} M^{\mathrm{rr}} ; \tag{E1}
\end{equation*}
$$

$w$ here $M^{p q}$ are the $2 \quad 2 \mathrm{~m}$ atrioes obtained for a single sm ooth interface in A ppendix $A$, depending on whether the upper and lower layers on the $n$-th interface are nonm agnetic or $m$ agnetic ones, respectively,
and $u{ }_{i n}$ and $d_{n}$ represent the refracted angle de ned in Eq. (A) and the thickness of the
 $R_{n}$ and $T_{n}$ are the vectors ( $R_{n ; 1} ; R_{n ; 2}$ ) and ( $T_{n ; 1} ; T_{n ; 2}$ ) representing the two waves re ected and transm itted, respectively, at the top of the $n$-th layer. (In Ref. 'ī, they are de ned at the bottom of the $n$-th layer.)

Introducing $W{ }_{n}^{\mathrm{pq}} \mathrm{m}$ atrices follow ing Ref. 1
and using the recursion form ulae involving $M_{n+1}^{p q} m$ atrices at the $n$-th interface, i.e.,
yields the follow ing recursion form ulae for $W{ }_{n}^{p q} m$ atrioes:

$$
\begin{align*}
& \mathrm{W}_{\mathrm{n}+1}^{\mathrm{tt}}=\mathrm{A}_{\mathrm{n}} \mathrm{~W}_{\mathrm{n}}^{\mathrm{tt}} \text {; } \\
& W{ }_{\mathrm{n}+1}^{\mathrm{tr}}=\mathrm{M}_{\mathrm{n}+1}^{\mathrm{tr}}+\mathrm{A}_{\mathrm{n}} \mathrm{~W}{ }_{\mathrm{n}}^{\mathrm{tr}} \mathrm{M}_{\mathrm{n}+1}^{\mathrm{rr}} \text {; } \\
& W{ }_{n+1}^{r t}=W{ }_{n}^{r t}+B_{n} M_{n+1}^{r t} W_{n}^{t t} \text {; } \\
& W{ }_{n+1}^{\mathrm{rr}}=\mathrm{B}_{\mathrm{n}} \mathrm{M}_{\mathrm{n}+1}^{\mathrm{rr}} \text {; } \tag{E5}
\end{align*}
$$

where $A_{n}$ and $B_{n}$ are de ned by

$$
\begin{array}{rlll}
A_{n}=M_{n+1}^{t t} & 1 & W_{n}^{r t} M_{n+1}^{r t} & 1
\end{array} ;
$$

Here $W{ }_{N}^{r t}$ determ ines the re ectivity of the whole multilayer, $R_{0}=W{ }_{N}{ }_{N}^{r t} T_{0}\left(R_{N}=0\right)$, from Eq. (EB).

Finally, the eld am plitudes $\mathrm{T}_{\mathrm{n}}, \mathrm{R}_{\mathrm{n}}$ inside the layers can be obtained from Eqs. (E) by

$$
\begin{align*}
\mathrm{R}_{\mathrm{n}} & =1 \mathrm{M}_{\mathrm{n}+1}^{\mathrm{rt}} \mathrm{~W}_{\mathrm{n}}^{\mathrm{tr}}{ }^{1} \mathrm{M}_{\mathrm{n}+1}^{\mathrm{rr}} \mathrm{R}_{\mathrm{n}+1}+\mathrm{M}_{\mathrm{n}+1}^{\mathrm{rt}} \mathrm{~W}_{\mathrm{n}}^{\mathrm{tt}} \mathrm{~T}_{0} ; \\
\mathrm{T}_{\mathrm{n}} & =\mathrm{W}{ }_{\mathrm{n}}^{\mathrm{tr}} \mathrm{~T}_{0}+\mathrm{W}_{\mathrm{n}}^{\mathrm{tr}} \mathrm{R}_{\mathrm{n}} ; \tag{E7}
\end{align*}
$$

which m ust be progressively applied to all the layers starting at the multilayer substrate where $R_{N}=0$.

E lectron ic address: 'drlee@ apsaniogo'
y A lso at D epartm ent of M aterials Science and Engineering, N orthw estem U niversity, E vanston, ㅍ. 60208

1 D . G ibbs, D. R . H arshm an, E. D. Isaacs, D. B . M cW han, D . M ills, and C . Vettier, Phys. R ev. Lett. 61, 1241 (1988).
${ }^{2}$ C.C.K ao, C.T.Chen, E.D. Johnson, J. B. H astings, H. J. Lin, G. H. H O, G. M eigs, J.M. B rot, S.L.H ulbert, Y.U.Idzerda, and C.Vettier, Phys. Rev. B50, 9599 (1994).
${ }^{3}$ E. D. Isaacs, D.B.M CW han, C.P eters, G.E. Ice, D. P. Siddons, J. B. H astings, C. Vettier, and O.Vogt, Phys. R ev. Lett. 62, 1671 (1989).
${ }^{4}$ D. B. M cW han, C.Vettier, E. D. Isaacs, G.E. Ice, D. P. Siddons, J. B. H astings, C. P eters, and O.Vogt, Phys. Rev. B 42, 6007 (1990).
$5^{5}$ K . N am ikaw a, M. A ndo, T.N aka j̈m a, and H. K aw ata, J. Phys. Soc. Jpn. 54, 4099 (1985).
6 J.P. H annon, G . T. Tram m ell, M . B hum e, and D.G ibbs, Phys. R ev. Lett. 61, 1245 (1988); 62, 2644 (E) (1989).
${ }^{7}$ M. B hum e and D. G ibbs, P hys. R ev. B 37, 1779 (1988).
8 M . D . H am rick, Ph D . thesis, R ige U niversity, 1994.
9 J.P. H ill and D.F.M dM orrow, A cta C rystallogr., Sect. A : Found. C rystallogr. 52, 236 (1996).
10 S.W . Lovesey and S.P.C ollins, X -ray Scattering and A bsonption by M agnetic M aterials (O xford U niversity P ress Inc., $N$ ew York, 1996).

11 J. M . Tonnerre, L. Seve, D. R aoux, G. Soullie, B. R odm acq, and P. W olfers, P hys. R ev. Lett. 75,740 (1995).

12 M . Sacchi, C . F. H ague, L. P asquali, A . M irone, J.M . M ariot, P . Isberg, E. M . G ullikson, and J. H. U nderw ood, P hys. Rev. Lett. 81, 1521 (1998).
${ }^{13}$ N. Ishim atsu, H. H ashizum e, S. H am ada, N. H osoito, C. S. N elson, C. T. Venkataram an, G. Srajer, and J. C . Lang, Phys. R ev. B 60, 9596 (1999).

14 D. H askel, G. Srajer, J. C . Lang, J. P ollm ann, C . S. N elson, J. S . Jiang, and S . D . B ader, P hys. Rev. Lett. 87, 207201 (2001).
${ }^{15}$ S.A. Stepanov and S.K.Sinha, P hys. Rev. B 61, 15302 (2000).
${ }^{16}$ R. R ohlsberger, H yper ne Interact $123 / 124$, 301 (1999).

17 S.K.Sinha, E.B.Sirota, S. G aro, and H.B. Stanley, Phys. Rev. B 38, 2297 (1988).
18 V. H oly and T. B aum bach, Phys. Rev. B 49, 10668 (1994).
19 R.M. O sgood III, S.K.Sinha, J.W .Freeland, Y.U.Idzerda, and S.D.B ader, J.M agn . M agn . M ater. 198-199, 698 (1999).

20 D.R.Lee, C.S.N elson, J. C.Lang, C.T.Venkataram an, G. Srajer, R.M. O sgood III, and S. K. Sinha, sulbm itted to P hys. R ev. B .

21 L. Nevot and P. C roce, Rev. Phys. A ppl. 15, 761 (1980).
22 D.K.G.de B oer, Phys. Rev. B 49, 5817 (1994).
23 B.Vidal and P.V incent, A ppl. Opt. B 23, 1794 (1984).
24 D.K.G.de B oer, P hys. Rev. B 44 , 498 (1991).
25 D . Bahr, W . P ress, R . Jebasinski, and S.M antl, P hys. R ev. B 47, 4385 (1993).
26 S.A. Stepanov and R.K ohler, J. A ppl. P hys. 76, 7809 (1994).
${ }^{27}$ R.E.C am ley, Phys. Rev.B 39, 12316 (1989).
28 D.R.Lee, Y. J. P ark, S.H.Park, Y.H.Jeong, K.B.Lee, N. Ishim atsu, H. H ashizum e, and N. H osoito, Physica B 248, 146 (1998).

29 J. C. Lang and G. Srajer, Rev. Sci. Instrum . 66, 1540 (1995).


F IG . 1: Schem atic of scattering geom etry and sketch of the chem ical (or structural) ( $z_{C}$ (x;y)) and $m$ agnetic $\left(z_{m}(x ; y)\right)$ interfaces, which can be separated from one another by an average am ount. Grazing angles of incidence ( ${ }_{i}$ ) and scattering $(f)$, the $w$ ave vectors $k_{i}$ and $k_{f}$, and the photon polarization vectors of incidence ( $(\mathrm{A}=$; ) and scattering ( $\mathrm{e}=$; ) are illustrated. Sm all arrow s represent the possible orientations of the $m$ agnetic $m$ om ents around $m$ agnetic interfaces.


FIG.2: Schem atic of an ideal interface with undisturbed states $E\left(k_{i}\right)$ and $E^{T}\left(k_{f}\right)$. N ote two possible waves for each of the re ected and transm itted w ave vectors.


FIG.3: C alculated x-ray resonant $m$ agnetic re ectivities at the $G d L_{3}$-edge ( 7243 eV ) from Gd surfaces $w$ ith di erent interfacial $w$ idths for structural ( $c$ ) and $m$ agnetic ( $m$ ) interfaces: (a)-(c) $\mathrm{c}=8 \mathrm{~A}, \mathrm{~m}=3 \mathrm{~A} .(\mathrm{d})-(\mathrm{f}) \mathrm{c}=3 \mathrm{~A}, \mathrm{~m}=8 \mathrm{~A}$. (g)-(i) sameas (d)-(f), butwith a 20A magnetically dead layer. Top panel: re ected intensities of the ! (solid lines) and ! (dashed lines) channels, and the di erences betw een the re ected intensities for right- ( $I_{+}$) and left- ( $I$ ) circularly polarized incident beam s (circles). M iddle panel: Natural logarithm s of the re ectivities with interface roughnesses nom alized to those from ideal system $s$ w thout roughness as a function of the square of the wave-vector transfer. Solid, dashed, and dot-dashed lines represent ! and
! scattering, and the di erences betw een $I_{+}$and I , respectively. Bottom panel: Norm alized scattering density pro les for charge (solid lines) and magnetic (dashed lines) scattering.


FIG. 4: Charge (a) and magnetic (b) x-ray scattering amplitudes, $f_{c, m}$ around the $G d L_{2}$-edge obtained from the absorption $m$ easurem ents for $a[G d(51 A) / F e(34 A)]_{15} m u l t i l a y e r . T$ he vertical lines indicate the photon energies, where the x-ray resonant magnetic re ectivities in $F$ ig. ', '5, were calculated.


F IG . 5: C alculated x-ray resonant magnetic re ectivities from a $[G d(51 A) / F e(34 A)]_{15} m$ ultilayer for di erent incident photon energies indicated in Fig. $\overline{4} 1 \mathbf{1}:$ (a) 7926 eV , (b) 7929 eV , (c) 7931 eV , and (d) 7935 eV . B oth structural (charge) and magnetic interface roughnesses are cm $=4: 7 \mathrm{~A}$ and 3.6 A for $\mathrm{Fe} / \mathrm{Gd}$ and $\mathrm{Gd} / \mathrm{Fe}$ interfaces, respectively. T he solid lines represent ( $\mathrm{I}_{+}+\mathrm{I}$ ) intensities and open ( lled) circles represent the positive (negative) values of ( $I_{+}$I ) intensities.


F IG . 6: C alculations w ith di erent $m$ agnetic interface roughnesses: (a) and (c) $m=2.1 \mathrm{~A}$, and (b) and (d) m = 62A. All other param eters and sym bols are sam e as those in F ig. $\overline{\mathrm{S}}$.


F IG . 7: M odels of m agnetic structures in Gd layers. U niform m agnetization (A ), ferrom agnetic m om ents only near the $\mathrm{Gd} / \mathrm{Fe}$ interfaces ( B ), and ferrom agnetic m om ents near the centers of G d layers betw een magnetically dead layers (C). W hile interfaces with \cr m" represent both structurally and $m$ agnetically $m$ ixed interfaces, interfaces $w$ ith $\backslash c$ " (or $\backslash \mathrm{m}$ ") represent purely structural (or magnetic) interfaœs.


FIG. 8: C alculated ( $I_{+}$I ) intensities for di erent $m$ agnetization depth pro les in G dayers. In (a)-(c) ferrom agnetic layens exist only near the $G d / F e$ interfaces $\mathbb{F}$ ig. inin (B)], and their layer thicknesses are 4.6 A (a), $8.4 \mathrm{~A} \quad$ (b), and 12.8 A (c). In (d)-(f) ferrom agnetic layers exist in the m iddle of G d layers and are sandw iched betw een m agnetically dead layers $\mathbb{F}$ ig. ${\underset{i}{1}}_{1}^{1}(C)]$, and the layer thicknesses of the dead layers are 4.6 A (d), 8.4 A (e), and $12.8 \mathrm{~A} \quad$ (f). A llm agnetic roughness amplitudes are $m=4: 2 \mathrm{~A}$, which is e ectively sameas c , and the photon energy is $\mathrm{E}=7929$ eV . A $l l$ other param eters and sym bols are sam e as those in $F$ ig. ${ }^{1 / 5 \cdot 1 .}$


FIG.9: ( $I_{+}+I$ ) [(a)] and ( $I_{+} \quad$ I $)[(b)]$ intensities $m$ easured (sym bols) from a Fe(34 A)/[Gd(51 A ) $/ \mathrm{Fe}(34 \mathrm{~A})]_{15} \mathrm{~m}$ ultilayer near the $\mathrm{Gd} \mathrm{L}_{2}$-edge (7929 eV ). T he lines represent the best theoretical ts $w$ ith the $m$ odel (B) in $F$ ig. $]_{-1}$. N ote that the colors of sym bols and lines in ( $I_{+} \quad$ ) intensities are di erent for opposite signs of the intensities.


FIG. 10: The representation chosen for the elem ents of $M{ }^{\mathrm{pq}} \mathrm{m}$ atrices w th the polarization bases of the incident and re ected (or transm 此ted) waves. Thepolarization basis is given by (e , e ), as show $n$ in $F$ ig. 1, for the $w$ aves in the nonm agnetic $m$ edium and $\left(e^{(1)}, e^{(2)}\right)$, as de ned in A ppendix $A$, for those in the resonant $m$ agnetic $m$ edium, respectively.

